

ProASIC™ 500K Family

Features and Benefits

- High Capacity
 - 98,000 to 1.1 Million System Gates
 - 14K to 138K Bit of Two-Port SRAM
 - 210 to 623 User I/Os
- Performance
 - Corner-to-Corner Delay < 4 ns (Typical)
 - Clock-to-Out < 7 ns
 - System Performance > 200MHz
- Low Power
 - Segmented Hierarchical Routing Structure
 - Small Efficient Logic Cells
 - Low-Power FLASH Switches
- High Performance Routing Hierarchy
 - Ultra Fast Local Network
 - Efficient Long Line Network
 - High Speed Bus Network
 - High Performance Global Network
- Nonvolatile and Reprogrammable FLASH Technology
 - Live at Power-Up
 - No Configuration Boot Device Required
 - Retains Programmed Design During Power-Down/Power-Up Cycles
- I/O
 - Mixed 3.3/2.5 Volt Support
 - 3.3V, 33MHz PCI Compliance (PCI Revision 2.2)
 - Individually Selectable 3.3V or 2.5V I/Os and Slew Rate (25, 50, and 100 mA/nsec)
- Secure Programming
 - Security Bit Prevents Read Back of Programming Bit Stream
- Standard FPGA and ASIC Design Flow
 - Flexibility to Choose Vendor-Specific Front-End Tools
 - Provide Efficient Design Through Front-End Timing and Gate Optimization
- In-System Programming (ISP) with Silicon Sculptor
- Embedded Memory Generator for SRAMs and FIFOs
 - Ensures Optimal Memory Usage
 - Up to 133MHz Synchronous and Asynchronous Operation
- IEEE Std. 1149.1 (JTAG) Compliant
- Individual ProASIC Device ID
 - Control and Restrict IP Delivery to Individual ProASIC Device

ProASIC Product Profile

| | A500K050 | A500K130 | A500K180 | A500K270 | A500K350 | A500K440 | A500K510 |
|--|----------|----------|----------|----------|----------|----------|-----------|
| Maximum System Gates | 98,000 | 287,000 | 369,000 | 473,000 | 638,000 | 956,000 | 1,100,000 |
| Typical Gates | 43,000 | 105,000 | 150,000 | 215,000 | 280,000 | 350,000 | 410,000 |
| Maximum Flip-Flops | 5,376 | 12,800 | 18,432 | 26,880 | 34,816 | 43,776 | 51,200 |
| Embedded RAM Bits | 14K | 46K | 55K | 65K | 74K | 124K | 138K |
| Embedded RAM Blocks (256 X 9) | 6 | 20 | 24 | 28 | 32 | 54 | 60 |
| Logic Tiles | 5,376 | 12,800 | 18,432 | 26,880 | 34,816 | 43,776 | 51,200 |
| Maximum User I/Os | 210 | 312 | 368 | 446 | 496 | 570 | 623 |
| JTAG | Yes |
| PCI | Yes |
| Package (by Pin Count) | | | | | | | |
| PQFP | 208 | 208 | 208 | 208 | | | |
| PBGA | 272 | 272, 456 | 456 | 456 | | | |
| FBGA | | | 580 | 580 | 580 | 580 | 580 |

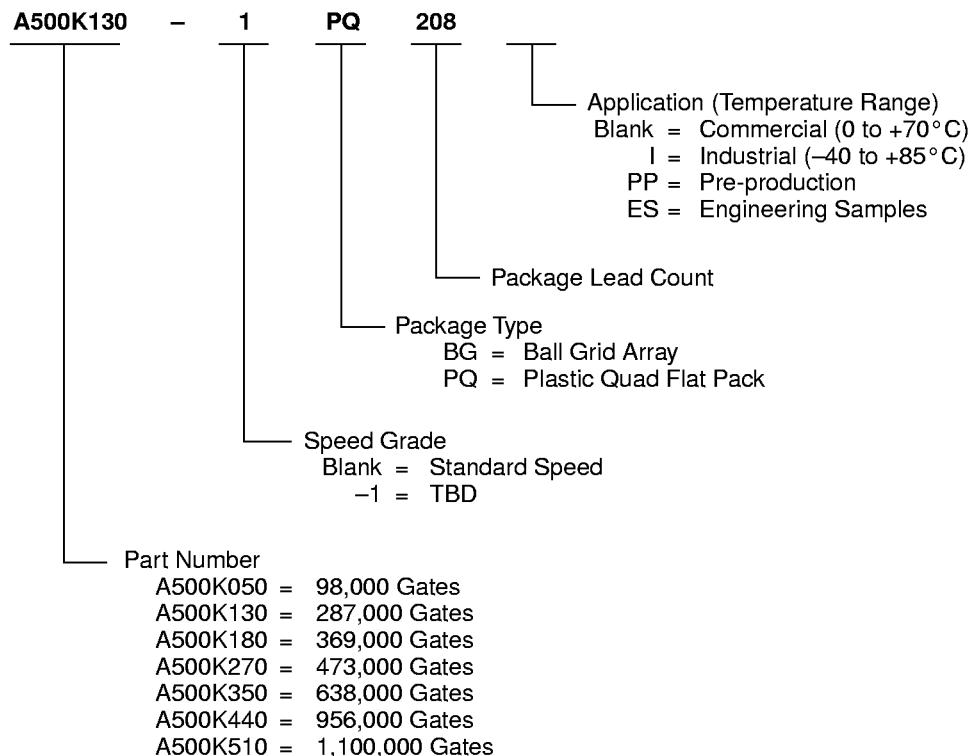
General Description

The 0.25 μ ProASIC 500K family combines the advantages of ASICs with the benefits of programmable devices through its nonvolatile FLASH technology. ProASIC 500K devices make it possible to create high-density systems using existing ASIC or FPGA design flows and tools, shortening time-to-production. ASIC migration is not necessary for any volume because the family offers cost effective reprogrammable solutions, ideal

for applications in the networking, telecom, computer, and consumer markets.

The ProASIC 500K family offers seven devices with 98K to 1.1M system gates and includes up to 138K bits of embedded two-port memory. These memory blocks include hardwired decoders, I/O circuits, parity generation and detection circuits, FIFO flow generation logic, and timing and control circuits to minimize external logic gate count and complexity while maximizing flexibility and utility.

Ordering Information



Product Plan

| | Speed Grade | | Application | |
|--|-------------|-----|-------------|---|
| | Std | -1* | C | I |
| A500K050 Device | | | | |
| 208-Pin Plastic Quad Flat Pack (PQFP) | ✓ | P | P | P |
| 272-Pin Plastic Ball Grid Array (PBGA) | ✓ | P | P | P |
| A500K130 Device | | | | |
| 208-Pin Plastic Quad Flat Pack (PQFP) | ✓ | P | P | P |
| 272-Pin Plastic Ball Grid Array (PBGA) | ✓ | P | P | P |
| 456-Pin Plastic Ball Grid Array (PBGA) | ✓ | P | P | P |
| A500K180 Device | | | | |
| 208-Pin Plastic Quad Flat Pack (PQFP) | ✓ | P | P | P |
| 456-Pin Plastic Ball Grid Array (PBGA) | ✓ | P | P | P |
| 580-Pin Fine Ball Grid Array (FBGA) | P | P | P | P |
| A500K270 Device | | | | |
| 208-Pin Plastic Quad Flat Pack (PQFP) | ✓ | P | P | P |
| 456-Pin Plastic Ball Grid Array (PBGA) | ✓ | P | P | P |
| 580-Pin Fine Ball Grid Array (FBGA) | P | P | P | P |
| A500K350 Device | | | | |
| 580-Pin Fine Ball Grid Array (FBGA) | P | P | P | P |
| A500K440 Device | | | | |
| 580-Pin Fine Ball Grid Array (FBGA) | P | P | P | P |
| A500K510 Device | | | | |
| 580-Pin Fine Ball Grid Array (FBGA) | P | P | P | P |

Contact your Actel sales representative for package availability.

Applications: C = Commercial Availability: ✓ = Limited Availability. Contact your Actel Sales representative for the latest I = Industrial availability information.

*Speed Grade: -1 = TBD P = Planned

Plastic Device Resources

| Device | User I/Os | | | |
|----------|-----------------|-----------------|-----------------|-----------------|
| | PQFP 208-Pin | PBGA 272-Pin | PBGA 456-Pin | FBGA 580-Pin |
| A500K050 | 170 | 210 | — | — |
| A500K130 | 170 | 210 | 312 | — |
| A500K180 | 170 | — | 368 | 368 |
| A500K270 | 170 | — | 368 | 446 |
| A500K350 | — | — | — | 496 |
| A500K440 | — | — | — | 496 |
| A500K510 | — | — | — | 496 |

Package Definitions (Contact your Actel sales representative for product availability.)

PQFP = Plastic Quad Flat Pack, PBGA = Plastic Ball Grid Array, FBGA = Fine Ball Grid Array

Pin Description

I/O User Input/Output

The I/O pin functions as an input, output, three-state, or bi-directional buffer. Input and output signal levels are compatible with standard TTL and CMOS specifications. Unused I/O pins are configured as inputs with pull-up resistor.

N/C No Connect

To maintain compatibility with future Actel ProASIC products it is recommended that this pin not be connected to the circuitry on the board.

G_X Global Input Pin

Low skew input pin for clock or other global signals. Input only.

GND Ground

Common ground supply voltage.

V_{DDL} Logic Array Power Supply Pin

2.5V supply voltage.

V_{DDP} I/O Pad Power Supply Pin

2.5V or 3.3V supply voltage.

V_{PP} Programming Supply Pin

This pin must be connected to V_{DDP} during normal operation, or it can remain at 16.5V in an ISP application. This pin must not float.

V_{PN} Programming Supply Pin

This pin must be connected to GND during normal operation, or it can remain at -12V in an ISP application. This pin must not float.

TMS Test Mode Select

The TMS pin controls the use of JTAG circuitry.

TCK Test Clock

Clock input pin for JTAG.

TDI Test Data In

Serial input for JTAG.

TDO Test Data Out

Serial output for JTAG.

RCK Running Clock

A free running clock is needed during programming if the programmer cannot guarantee that TCK will be uninterrupted.

Process Technology

The ProASIC 500K family achieves its non-volatility and reprogrammability through an advanced 4LM FLASH-based 0.25 μ channel length CMOS technology process. Standard CMOS design techniques are used to implement logic and control functions resulting in highly predictable performance and gate array compatibility. FLASH memory bits are

distributed throughout each device providing non-volatile, reconfigurable interconnect programming.

ProASIC 500K Architecture

The ProASIC 500K family utilizes a proprietary architecture that results in granularity comparable to gate arrays. Unlike SRAM-based FPGAs, ProASIC devices do not utilize look-up tables or architectural mapping during design. Instead, designs are directly synthesized to gates that streamline the design flow, increase design productivity, and eliminate dependencies on vendor-specific design tools.

The ProASIC 500K device core consists of a Sea-of-Tiles™ (Figure 1). Each logic tile can be configured into a 3-input logic function (i.e. NAND gate, D-Flip-Flop, etc.) by programming the appropriate interconnect FLASH switches. Gates and larger functions are connected together in a similar manner utilizing the four levels of routing hierarchy. FLASH switches are programmed to connect signal lines to the appropriate logic cell inputs and outputs. Dedicated high-performance lines are connected as needed for fast, low-skew clock distribution throughout the core. All core tiles are configurable as gates, muxes, latches, or flip-flops. Maximum core utilization is possible for virtually any design.

The ProASIC 500K devices also contain embedded two-port SRAM blocks that have built in FIFO control logic. Programming options include synchronous or asynchronous operation, two-port RAM configurations, user defined depth and width, and parity selection.

Routing Resources

The routing structure of the ProASIC 500K devices is designed to provide high performance through routing flexibility. It is composed of four levels of hierarchical resources: ultra fast local resources, efficient long line resources, high speed bus resources, and high performance global networks.

The ultra fast local resources are high speed dedicated lines that allow the output of each tile to directly connect to every input of the eight closest tiles (Figure 2).

The efficient long line resources provide routing for longer distance and higher fanout connections. These resources vary in length (typically spanning 1, 2, or 4 tiles), run both vertically and horizontally, and cover the entire ProASIC device (Figure 2). Each tile can drive signals onto the efficient long line resources, and the resources can access every input of a tile. Active buffers are inserted automatically by the ASICmaster software to limit the effects of loading due to distance and fanout.

The high speed bus resources span across the entire device with minimal delay and are used to route very long or very high fanout nets. These resources run vertically and

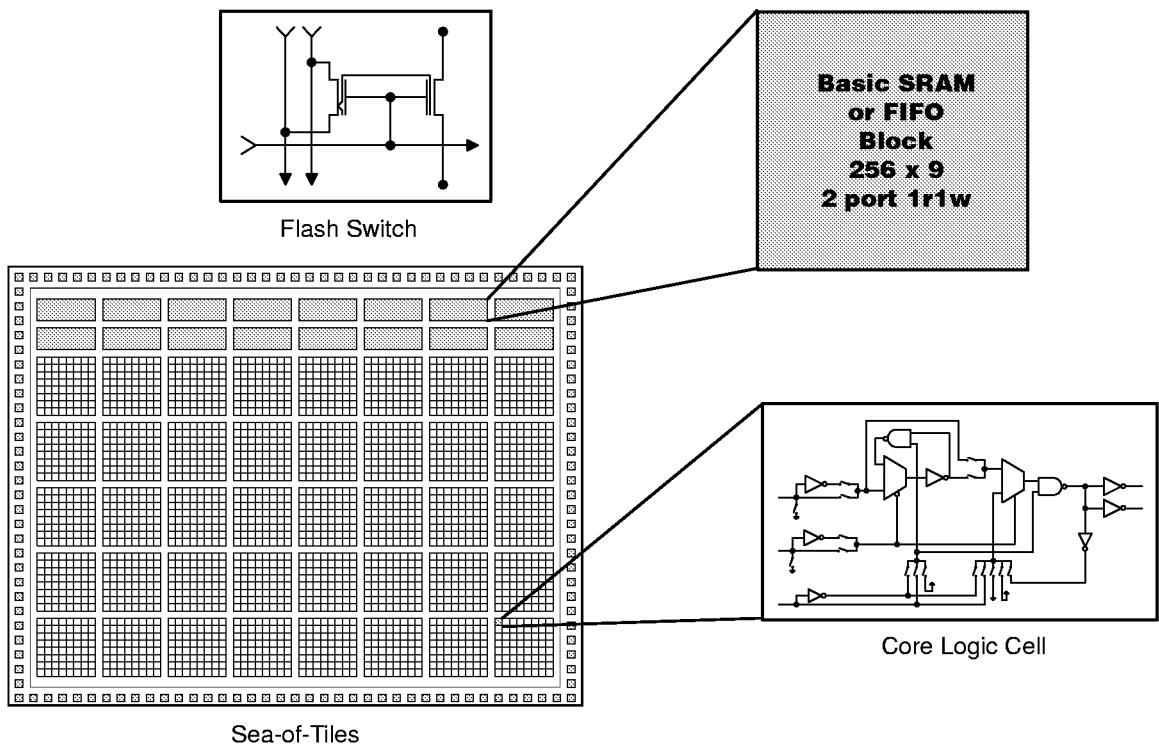


Figure 1 • The ProASIC Device Architecture

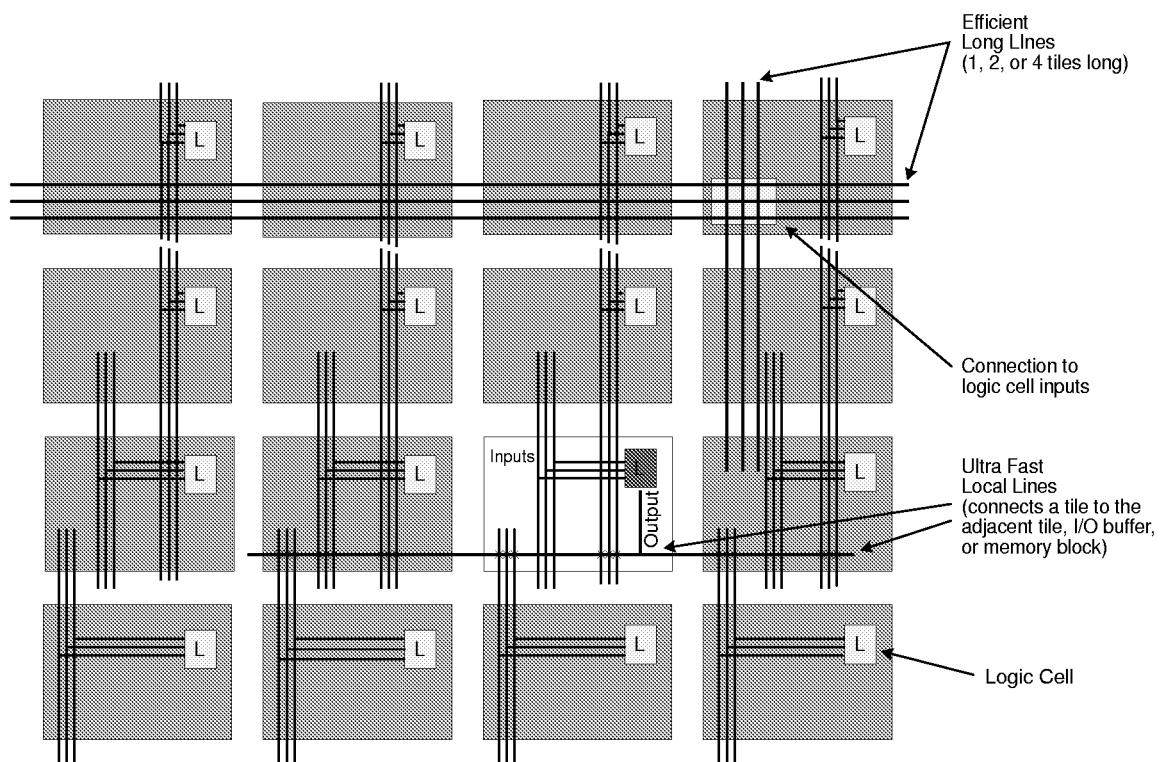


Figure 2 • High Density Interconnect

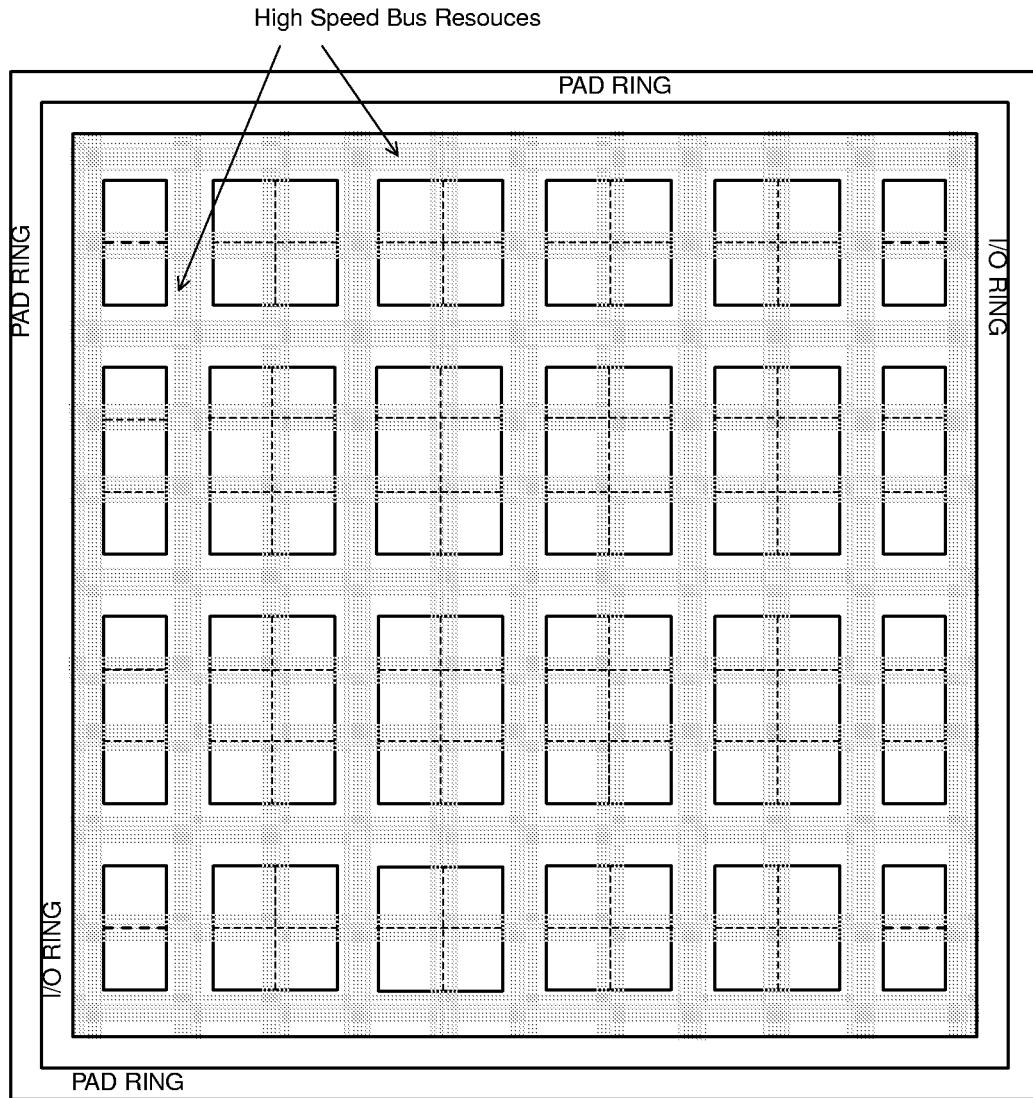


Figure 3 • High Speed Bus Resources

horizontally, and provide multiple access to each group of 16 tiles throughout the device (Figure 3).

The high performance global networks are low skew, high fanout nets that are accessible from four dedicated pins or from external logic (Figure 4). These nets are typically used to distribute clocks, resets, and other nets requiring high fanout with guaranteed minimum skew. The maximum delay on these nets is 3.5ns, and maximum skew is 250ps when these signals are used to drive clocks and resets on flip-flops. The global networks are implemented as four H trees, and signals can be introduced at any junction. These can be used hierarchically, with signals accessing every input on all tiles. Any portion of the global resources not required for the four primary global nets are made available to any other net requiring the distribution of high fanout signals.

Input/Output Blocks

To meet the needs of complex system designs, the ProASIC 500K family provides devices with a large number of I/O pins, with the A500K510 device offering up to 623 user I/O pins. The I/O pad is powered at 3.3V, which allows each I/O to be selectively configured at 2.5V and 3.3V compliant threshold levels. Figure 5 illustrates I/O interfaces with other devices. All I/Os also include an ESD protection circuit. Each I/O is tested according to the following models:

| | |
|-------------------------------|-------|
| Human Body Model (HBM) | 1500V |
| (Per Mil Std 883 Method 3015) | |
| Machine Model | 200V |

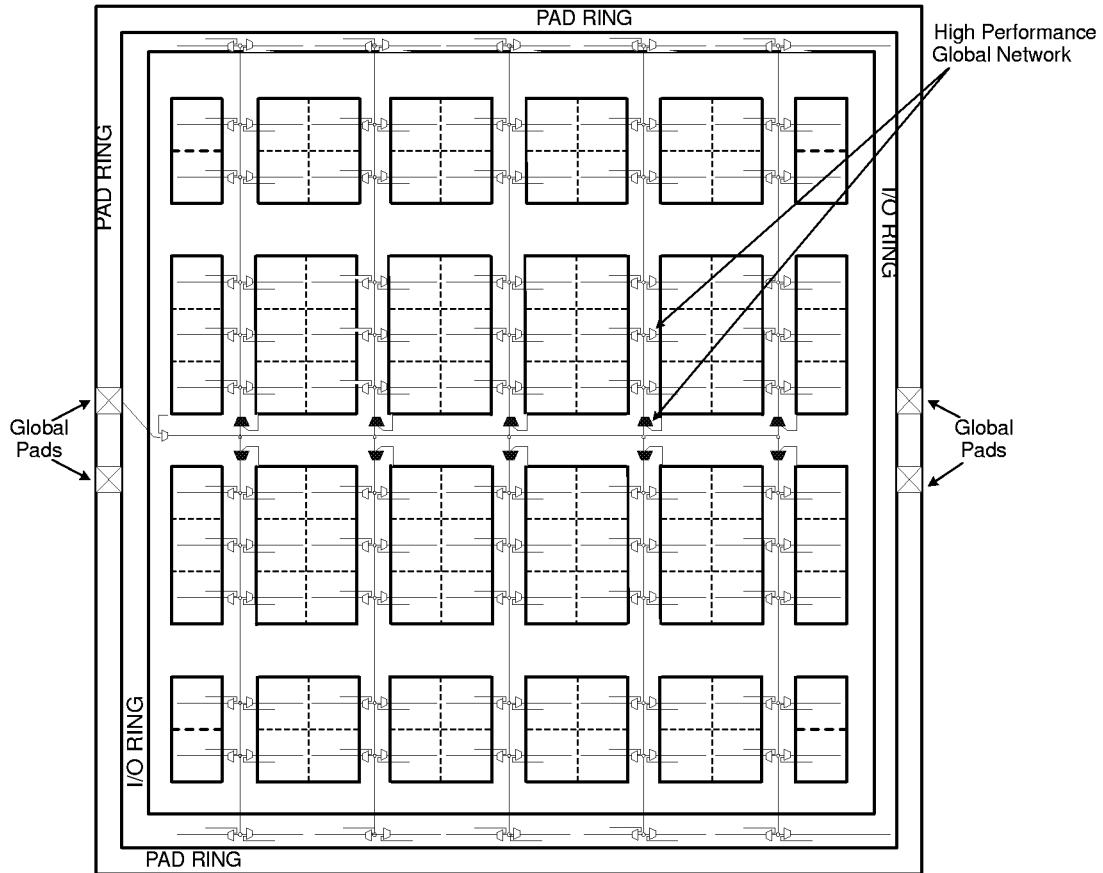


Figure 4 • High Performance Global Network

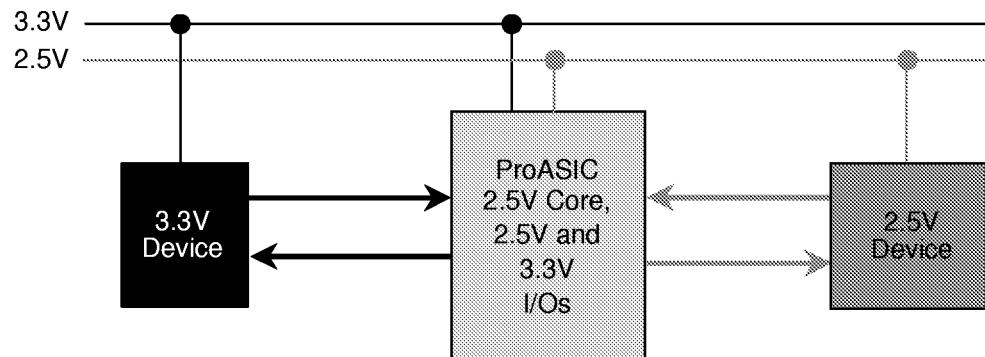


Figure 5 • I/O Interfaces

The I/O pads are fully configurable to provide the maximum flexibility and speed. Each pad can be configured as an input, an output, a three-state driver, or a bi-directional buffer (Figure 6). I/O pads configured as inputs have the following features:

- Individually selectable 3.3V or 2.5V compliant threshold levels
- Optional pull-up resistor

I/O pads configured as output have the following features:

- Individually selectable 3.3V or 2.5V compliant output signals
- 3.3V PCI compliant
- Ability to drive TTL and CMOS levels
- Selectable drive strengths
- Selectable slew rates
- Three-state enable (drivable from any internal or external signal)

I/O pads configured as bi-directional have the following features:

- Individually selectable 3.3V or 2.5V compliant output signals and threshold levels
- 3.3V PCI compliant
- Ability to drive TTL level
- Optional pull-up resistor for inputs
- Selectable drive strengths
- Selectable slew rates
- Three-state enable

User Security and Traceability

The ProASIC 500K devices have a read-protect bit that, once programmed, prevents the programming content from being read from the part. To clear the read-protect bit, the entire part must be erased. This capability lets you secure the programmed design and prevent it from being read back and duplicated. For traceability a 12-character alphanumeric user part number field allows the user to assign a user part ID, which can subsequently be read back by the programmer.

Embedded Memory Floorplan

The embedded memory is located across the top of the device (see Figure 1). Depending upon the device, 6 to 60 (256x9) blocks of memory are available to support a variety of possible memory configurations. Each block can be programmed as an independent memory or combined, using dedicated memory routing resources, to form larger and more complex memories.

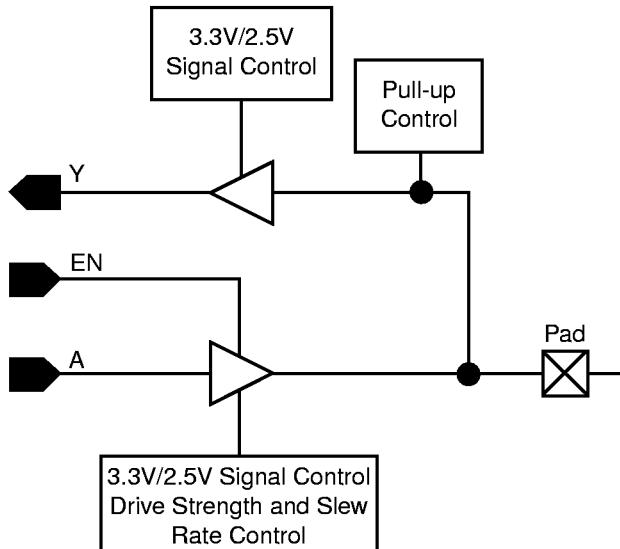


Figure 6 • I/O Block Schematic Representation

Embedded Memory Configurations

The embedded memory in the ProASIC 500K family offers great flexibility in memory configuration. Whereas other programmable vendors typically provide single port memories that can be transformed into a two-port memory at the loss of half the memory, each ProASIC block is designed and optimized as a two-port memory (1r1w). This provides 138K total memory bits for two-port and single port memory usage in the A500K510 device.

Each memory can be configured as a FIFO or SRAM, with independent selection of synchronous or asynchronous read and write ports. However, multiple writes are not supported. Additional characteristics include programmable FIFO flags and selectable depth, and parity check and generation. Figure 7 and Figure 8 show the block diagram of the basic SRAM and FIFO blocks. These memories are designed to operate at up to 133 MHz when operated individually. Each block contains a 256 word deep by 9-bit wide (1r, 1w) memory. The memory blocks shown in Figure 9 may be combined in parallel to form wider memories or stacked to form deeper memories. The MEMORYmaster™ software facilitates an easy means of building wider and deeper memories for optimal memory usage. This provides optimal bit widths of 9 (1 block), 18, 36, and 72. MEMORYmaster allows any bit width up to 252 (for the A500K270 device), but if an intermediate bit width is chosen, such as 16 bits, the remaining two bits are no longer accessible for other memories. MEMORYmaster also enables optimal memory stacking in 256 word increments. However, any word depth may be compiled for up to 7,168 words.

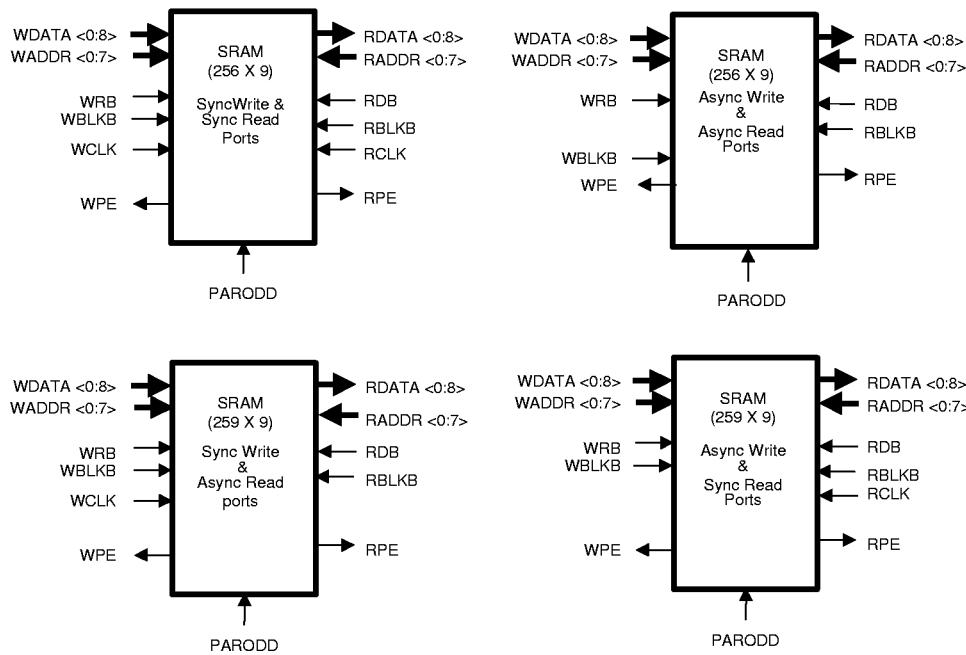
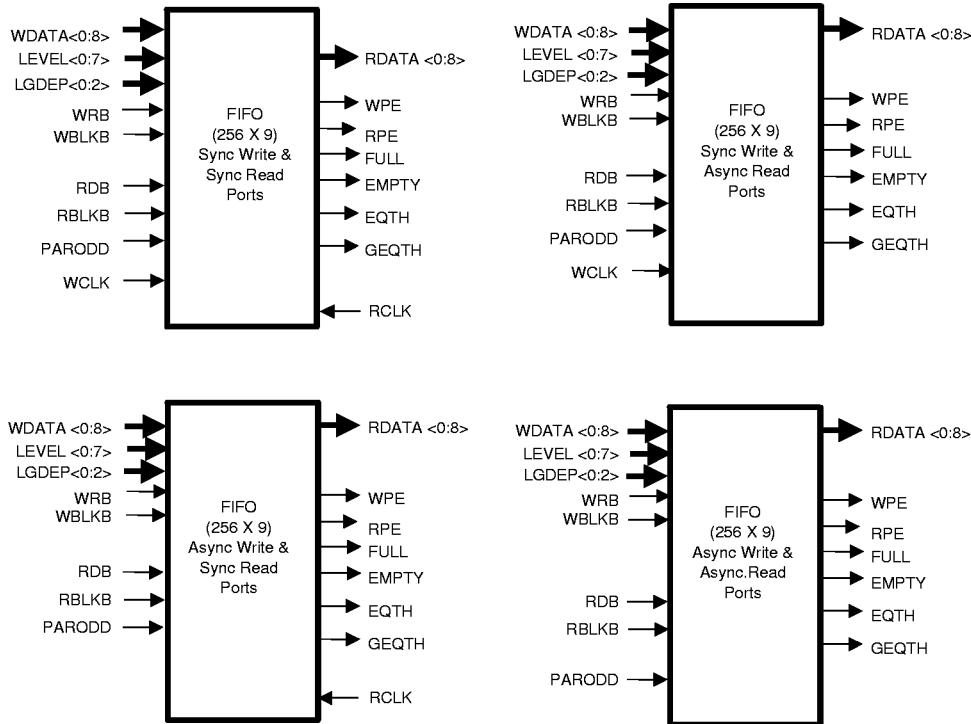
**Figure 7 • Example SRAM Block Diagrams****Figure 8 • Basic FIFO Block Diagrams**

Figure 10 shows an example of optimal memory usage. Three memories have been compiled with various widths and depths using 10 blocks and consuming all 23,040 bits. Figure 11 shows an example of doubling up memory to create extra read

ports. In this example, 10 out of 60 blocks of the A500K510 are fully used, but yield an effective 6,912 bits of multiple port memories.

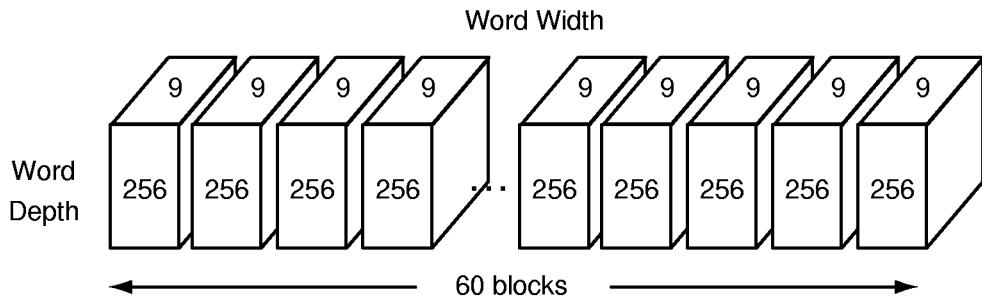


Figure 9 • A500K510 Memory Block Architecture

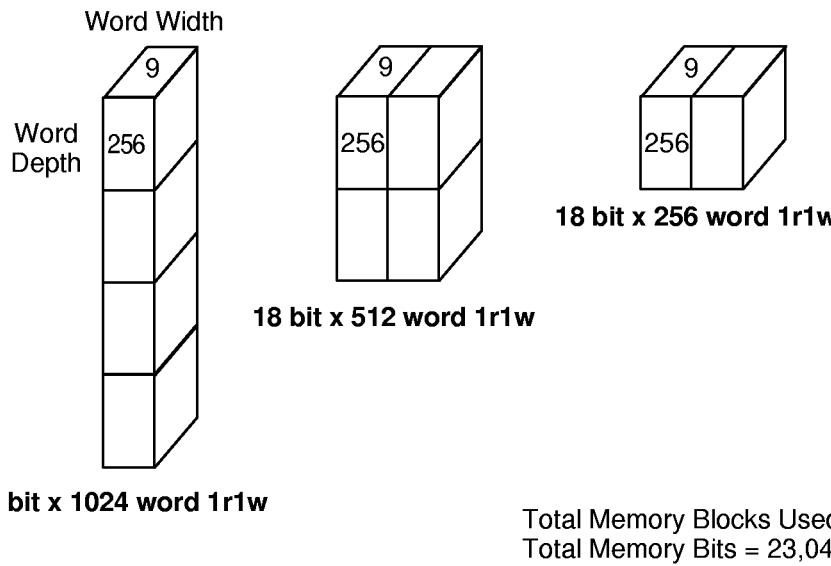


Figure 10 • Memories with Different Width and Depth

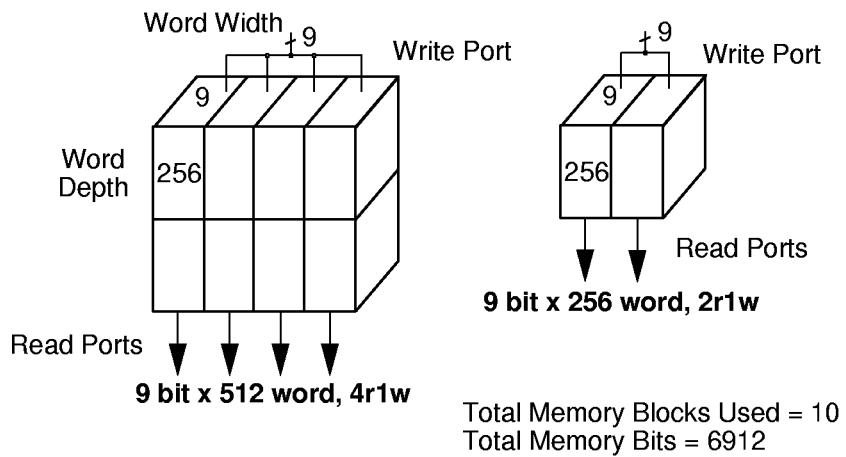


Figure 11 • Multiport Memory Usage

Design Environment

ProASIC devices are supported by Actel's ASICmaster and MEMORYmaster software, as well as third party CAE tools. Using the standard VHDL or Verilog HDL descriptions, no special HDL design techniques, required by some FPGA vendors, are needed. This allows designers to use the same code that is used for gate arrays and standard cells for ProASIC devices. The ProASIC design flow also ensures a seamless transition to an ASIC should production volumes warrant a migration to a gate array or a standard cell product. As shown in Figure 12, with identical HDL, design tools, and flow, migration to ASICs for high volume production is greatly simplified. Conversely, migration from ASICs to ProASIC technology is also free of traditional FPGA design requirements.

MEMORYmaster automatically generates memories from inputs given by the designer. The designer can select the depth and width, usage of parity generation or check, and synchronous or asynchronous functionality of the ports. If it is a synchronous read port, the designer can choose whether the output is pipelined or transparent.

Synthesis and simulation is performed by third party CAE tools. ProASIC is currently supported by Synopsys Design Compiler, Prime Time, and VSS, Cadence BuildGates and Verilog-XL, Exemplar Spectrum, and Model Technology ModelSim. Actel's ProASIC libraries and timing models provide the database required for simulation.

Place and route is performed by Actel's ASICmaster software. Available for SunOS, Solaris, HP, and Windows NT, it accepts standard ASIC formatted netlists, performs place and route of the design into the selected device and provides post layout delay information for back annotation simulation or static timing analysis. The ASICmaster software also contains very powerful interactive layout capabilities for the experienced user.

Once the design is finalized, the programming bitstream is downloaded into the device programmer for ProASIC part programming. ProASIC 500K devices can be programmed with the Silicon Sculptor programmer. In-System Programming is available using the Silicon Sculptor programmer and an In-System Programming header.

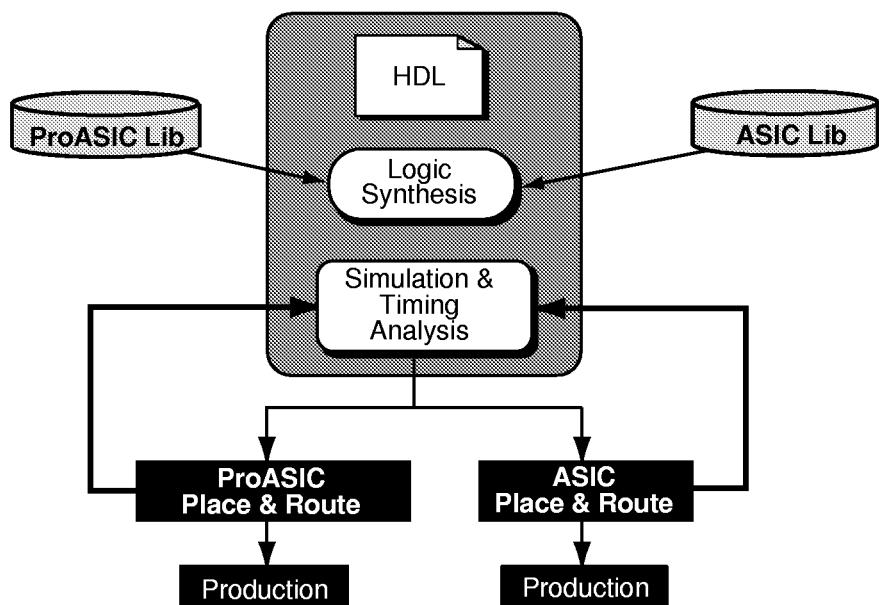


Figure 12 • Common Design Environment

Package Thermal Characteristics

The ProASIC 500K family is available in a number of package types. Packages are selected based on high pin count, reliability factors, and superior thermal characteristics.

The ability of a package to conduct heat away from the silicon, through the package to the surrounding air is expressed in terms of thermal resistance. This junction-to-ambient thermal resistance is measured in degrees Celsius/Watt and is represented as Theta JA (Θ_{JA}). The lower this thermal resistance, the easier it is for the package to dissipate heat.

The maximum allowed power (P) for a package is a function of the maximum junction temperature (T_J), the maximum ambient operating temperature (T_A), and the junction-to-ambient thermal resistance Θ_{JA} . Maximum junction temperature is the maximum temperature on the active surface of the IC and is 110° C. P is defined as:

$$P = \frac{T_J - T_A}{\Theta_{JA}}$$

| Package Type | Pin Count | Θ_{JC} | Θ_{JA} Still Air | Θ_{JA} 300 ft/min | Units |
|--------------------------------|-----------|---------------|-------------------------|--------------------------|-------|
| Plastic Quad Flat Pack (PQFP) | 208 | 3.5 | 20 | 17 | °C/W |
| Plastic Ball Grid Array (PBGA) | 272 | 3 | 20 | 16.5 | °C/W |
| Plastic Ball Grid Array (PBGA) | 456 | 3 | 16.5 | 14.5 | °C/W |

Calculating Power Dissipation

ProASIC device power is calculated in the same manner as CMOS gate arrays and includes both a static and an active component. The active component is a function of both the number of tiles utilized and the speed. ASICmaster provides an automatic power calculator that can be used to quickly and easily calculate power dissipation. Power dissipation can also be calculated using the following formula:

$$P = V_{DD} \cdot I_{DD}$$

where

$$I_{DD} = I_{STATIC} + I_{OUTPUT} + I_{LOGIC}$$

and

$$I_{STATIC} = I_{STATIC CORE} + I_{STATIC I/O}$$

I_{OUTPUT} is the current due to the outputs switching.

I_{LOGIC} is the current due to the internal logic signals switching.

The static power (I_{STATIC}) is the amount of current drawn when no inputs are switching. This is equal to the Quiescent Supply Current I_{DDQ} specified under DC Characteristics.

Θ_{JA} is a function of the rate of airflow in contact with the package, in linear feet per minute (lfpm). When the estimated power consumption exceeds the maximum allowed power, other means of cooling must be used, such as increasing the airflow rate.

The junction-to-case thermal resistance, Theta JC (Θ_{JC}), is the lowest possible thermal resistance of the device. Θ_{JC} is defined as:

$$\Theta = \Theta_{JC} + \Theta_{CA}$$

where

Θ_{CA} = case to ambient thermal resistance

Active power includes both the current due to outputs switching and the current due to internal logic signals switching.

$$I_{OUTPUT} = \sum_{i=1}^n (C_i \cdot V_i \cdot f_i + I_{DCi})$$

where

C_i is the capacitance on the i th output pad.

V_i is the voltage swing on the i th output pad.

f_i is the switching frequency on the i th output pad.

n is the number of outputs.

I_{DCi} is the average DC load on each pad, if any.

In most cases I_{OUTPUT} can be approximated by the following formula, measured in mA:

$$I_{OUTPUT} = n \cdot C_{typ} \cdot V \cdot f_{avg}$$

where

n is the number of active outputs.

C_{typ} is the typical capacitance load on an output.

V is the average voltage swing.

f_{avg} is the average switching frequency of the outputs. Typically this is less than 25% of the clock frequency.

I_{LOGIC} is represented by this formula, measured in mA:

$$I_{LOGIC} = I_E \cdot G \cdot f \cdot F$$

where

I_E is the effective μ A per gate per MHz of the Actel parts. For the ProASIC products the value is 1.2.

G is the number of gates used in the design, in thousands.

f is the operating frequency in MHz.

F is the fraction of devices active on each clock edge. F varies for different designs, but 0.15 is a conservative and commonly used value.

For a A500K130 design that has 47,000 used gates, 20 memory blocks, 150 active outputs, an average load of 20 pF, and a 66 MHz clock, resulting in an average switching frequency of 16.5 MHz, the power calculation appears below.

$$\begin{aligned} I_{OUTPUT} &= 150 \cdot 20 \cdot 10^{-12} \cdot 3.6 \cdot 16.5 \cdot 10^6 \text{mA} \\ &= 140 \text{mA} \end{aligned}$$

$$P_{OUTPUT} = 3.6V \cdot 140 \text{mA} = .5W$$

$$\begin{aligned} I_{LOGIC} &= 1.2 \cdot 47 \cdot 66 \cdot 0.15 \text{mA} \\ &= 558 \text{mA} \end{aligned}$$

Therefore

$$I_{LOGIC} = 558 \text{mA}$$

$$\begin{aligned} P_{Logic} &= 2.75V \cdot 558 \text{mA} \\ &= 1.5 \text{W} \end{aligned}$$

Assumptions .5K gates per 256x9 block

$$\begin{aligned} I_{memory} &= 1.2 \cdot .5 \cdot 66 \cdot .15 \cdot 20 \text{mA} \\ &= 118 \text{mA} \end{aligned}$$

$$P_{memory} = 2.75V \cdot 143 \text{mA} = .326$$

$$P = 1.5 \text{W} + .5 \text{W} + .32 \text{W} = 2.32 \text{W}$$

$I_{STATIC CORE}$ and $I_{STATIC I/O}$ are not included in this calculation.

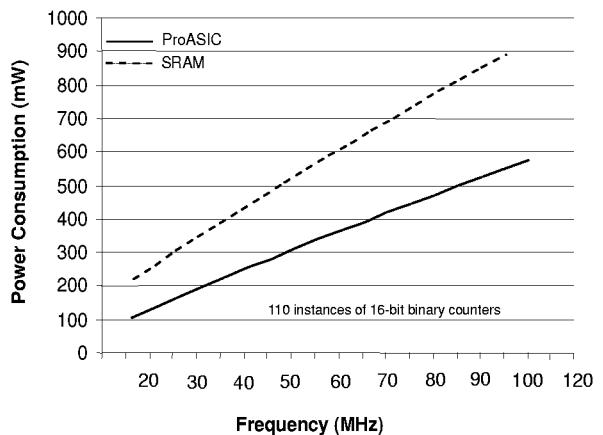


Figure 13 • Power Consumption of a 500K Device

Operating Conditions

Absolute Maximum Ratings

| Parameter | Condition | Minimum | Maximum | Units |
|---|----------------------------|---------|-----------------|-------|
| Supply Voltage Core (V_{DDL}) | | -0.3 | 3.0 | V |
| Supply Voltage IO Ring (V_{DDP}) | | -0.3 | 4.0 | V |
| DC Input Voltage | | -0.3 | $V_{DDP} + 0.3$ | V |
| PCI DC Input Voltage | | -0.5 | $V_{DDP} + 0.5$ | V |
| DC Input Clamp Current (I _{IK}) | $V_{IN} < 0$ or $> V_{DD}$ | -10 | +10 | mA |

Note: Stresses beyond those listed under Absolute Maximum ratings can cause permanent damage to the device. Exposure to maximum rated conditions for extended periods can adversely affect device reliability. Operation of the device at these conditions or any others beyond those listed under Recommended Operating Conditions shown in the table below is not implied.

Temperature Maximums

| Parameter | Min. | Max. | Units | Program Retention |
|--------------------------------|------|------|-------|-------------------|
| Storage Temperature | -65 | +150 | °C | NA |
| Storage Temperature—Programmed | -65 | +110 | °C | 20 years |

Programming Limits and Recommended Operating Conditions

| Product Grade | Programming Cycles | Program Retention | Junction Temperature | |
|---------------|--------------------|-------------------|----------------------|-------|
| | | | Min. | Max. |
| Commercial | 500 | 20 years | 0°C | 110°C |
| Industrial | 500 | 20 years | -40°C | 110°C |

Supply Voltages

| V_{DDL} | V_{DDP} | V_{PP} | V_{PN} |
|-----------|-----------|-------------------------------|----------------------------|
| 2.5V | 2.5V | $2.5V \leq V_{PP} \leq 16.5V$ | $-12V \leq V_{PN} \leq 0V$ |
| 2.5V | 3.3V | $2.5V \leq V_{PP} \leq 16.5V$ | $-12V \leq V_{PN} \leq 0V$ |

Recommended Operating Conditions

| Parameter | Symbol | Limits |
|--|-----------------------|----------------|
| Commercial | | |
| DC Supply Voltage (2.5V I/Os) | V_{DDL} & V_{DDP} | 2.30V to 2.70V |
| DC Supply Voltage (3.3V I/Os) | V_{DDP} | 3.0V to 3.6V |
| Operation Ambient Temperature Range | T_A | 0°C to 70°C |
| Operation Junction Temperature (maximum) | T_J | ≤ 110°C |
| Industrial | | |
| DC Supply Voltage (2.5V I/Os) | V_{DDL} & V_{DDP} | 2.30V to 2.70V |
| DC Supply Voltage (3.3V I/Os) | V_{DDP} | 3.0V to 3.6V |
| Operation Ambient Temperature Range | T_A | -40°C to 85°C |
| Operation Junction Temperature (maximum) | T_J | ≤ 110°C |

DC Electrical Specifications ($V_{DDP} = 2.5V$)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|-----------------------|--|--|--|------|--|---------------|
| V_{DDP} , V_{DDL} | Supply Voltage | | 2.30 | | 2.7 | V |
| V_{OH} | Output High Voltage High Drive Low Drive | $I_{OH} = -2.0 \text{ mA}$ $I_{OH} = -4.0 \text{ mA}$ $I_{OH} = -8.0 \text{ mA}$ $I_{OH} = -1.0 \text{ mA}$ $I_{OH} = -2.0 \text{ mA}$ $I_{OH} = -4.0 \text{ mA}$ | 2.1 2.0 1.7 2.1 2.0 1.7 | | | V |
| V_{OL} | Output Low Voltage High Drive Low Drive | $I_{OL} = 5.0 \text{ mA}$ $I_{OL} = 10.0 \text{ mA}$ $I_{OL} = 15.0 \text{ mA}$ $I_{OL} = 2.0 \text{ mA}$ $I_{OL} = 3.5 \text{ mA}$ $I_{OL} = 5.0 \text{ mA}$ | | | 0.2 0.4 0.7 0.2 0.4 0.7 | V |
| V_{IH} | Input High Voltage | | 1.7 | | $V_{DDP} + .03$ | V |
| V_{IL} | Input Low Voltage | | -0.3 | | .7 | V |
| V_T | Switching Threshold | | | 1.20 | | V |
| I_{IN} | Input Current (with pull-up) | | -20 | | -100 | μA |
| I_{DDQ} | Quiescent Supply Current | $V_{IN} = V_{SS}^*$ or V_{DDL} | | 1.0 | 10 | mA |
| I_{OZ} | 3-State Output Leakage Current | $V_{OH} = V_{SS}$ or V_{DDL} | -10 | | +10 | μA |
| I_{OSH} | Output Short Circuit Current High High Drive Low Drive | | | | -120 -100 | mA |
| I_{OSL} | Output Short Circuit Current Low High Drive Low Drive | | | | 100 30 | mA |
| $C_{I/O}$ | I/O pad capacitance | | | | 8 | pF |
| C_{CLK} | Clock input pad capacitance | | | | 8 | pF |

Notes: All process conditions. Junction Temperature: -40 to +110°C.

* No pull-up resistor.

DC Electrical Specifications ($V_{DDP} = 3.3V$)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|-----------|---|---|--|-------------------------------|--|---------------|
| V_{DDP} | Supply Voltage | | 3.0 | | 3.6 | V |
| V_{DDL} | Supply Voltage, Logic Array | | 2.3 | | 2.7 | V |
| V_{OH} | Output High Voltage 3.3V I/O, High Drive 3.3V I/O, Low Drive 2.5V I/O, High Drive 2.5V I/O, Low Drive | $I_{OH} = -3.0 \text{ mA}$ $I_{OH} = -5.0 \text{ mA}$ $I_{OH} = -10.0 \text{ mA}$ $I_{OH} = -2.0 \text{ mA}$ $I_{OH} = -3.0 \text{ mA}$ $I_{OH} = -6.0 \text{ mA}$ $I_{OH} = -0.5 \text{ mA}$ $I_{OH} = -1.0 \text{ mA}$ $I_{OH} = -2.0 \text{ mA}$ $I_{OH} = -0.5 \text{ mA}$ $I_{OH} = -1.0 \text{ mA}$ $I_{OH} = -2.0 \text{ mA}$ | $V_{DDP} - 0.2$ $0.9 * V_{DDP}$ 2.4 $V_{DDP} - 0.2$ $0.9 * V_{DDP}$ 2.4 2.1 2.0 1.7 2.1 2.0 1.7 | | | V |
| V_{OL} | Output Low Voltage 3.3V I/O, High Drive 3.3V I/O, Low Drive 2.5V I/O, High Drive 2.5V I/O, Low Drive | $I_{OL} = 7.5 \text{ mA}$ $I_{OL} = 12.0 \text{ mA}$ $I_{OL} = 15.0 \text{ mA}$ $I_{OL} = 2.5 \text{ mA}$ $I_{OL} = 4.0 \text{ mA}$ $I_{OL} = 5.0 \text{ mA}$ $I_{OL} = 7.5 \text{ mA}$ $I_{OL} = 15.0 \text{ mA}$ $I_{OL} = 24.0 \text{ mA}$ $I_{OL} = 2.5 \text{ mA}$ $I_{OL} = 5.0 \text{ mA}$ $I_{OL} = 8.0 \text{ mA}$ | | | 0.2 0.1 * V_{DDP} 0.4 0.2 0.1 * V_{DDP} 0.4 0.2 0.4 0.7 0.2 0.4 0.7 | V |
| V_{IH} | Input High Voltage TTL LV-CMOS 2.5V Mode | | 2 0.7 * V_{DDP} 1.7 | | $V_{DD} + .3$ | V |
| V_{IL} | Input Low Voltage TTL LV-CMOS 2.5V Mode | | -0.3 | | 0.8 0.3 * V_{DDP} 0.7 | V |
| V_T | Switching Threshold | TTL LV-CMOS 2.5V Mode | | 1.5 0.5 * V_{DDP} 1.2 | | V |
| I_{IN} | Input Current CMOS & TTL (with pull-up) | | -40 | | -200 | μA |
| I_{DDQ} | Quiescent Supply Current | $V_{IN} = V_{SS}^*$ or V_{DD} | | 1.0 | 10 | mA |

Notes: Refer to PCI Specifications Revision 2.2, for 3.3V high drive, high slew-rate output pads, and all 3.3V input/clock pads.

* No pull-up resistor.

DC Electrical Specifications ($V_{DDP} = 3.3V$)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|-----------|---|-------------------------------|------|------|------------------------------|---------|
| I_{OZ} | 3-State Output Leakage Current | $V_{OH} = V_{SS}$ or V_{DD} | -10 | | +10 | μA |
| I_{OSH} | Output Short Circuit Current High 3.3V I/O, High Drive 3.3V I/O, Low Drive 2.5V I/O, High Drive 2.5V I/O, Low Drive | | | | -200 -140 -100 -100 | mA |
| I_{OSL} | Output Short Circuit Current Low 3.3V I/O, High Drive 3.3V I/O, Low Drive 2.5V I/O, High Drive 2.5V I/O, Low Drive | | | | 160 50 160 50 | mA |
| $C_{I/O}$ | I/O pad capacitance | | | | 8 | pF |
| C_{CLK} | Clock input pad capacitance | | | | 8 | pF |

Notes: Refer to PCI Specifications Revision 2.2, for 3.3V high drive, high slew-rate output pads, and all 3.3V input/clock pads.

*No pull-up resistor.

Timing Characteristics

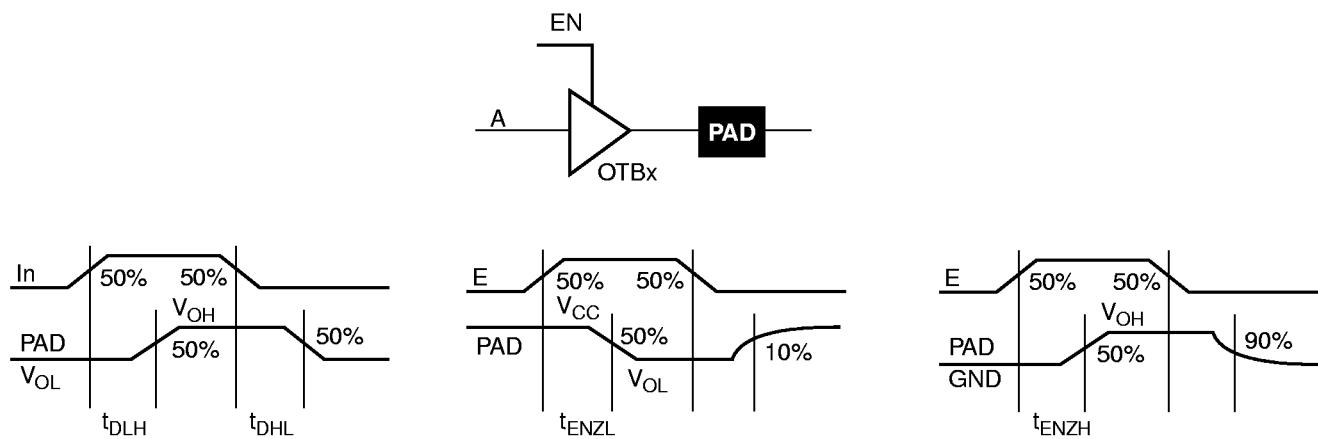


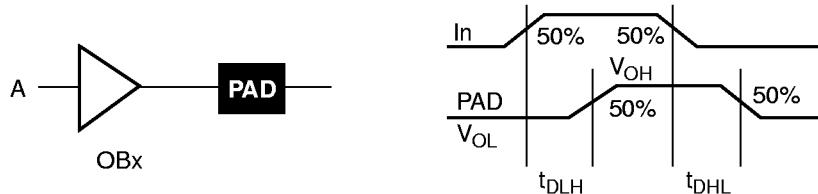
Figure 14 • Tristate Buffer Delays

Table 1 • Tristate Buffer Delays (Worst-Case Commercial Conditions, $V_{DDP} = 3.0V$, $V_{DDL} = 2.3V$, $35pF$ load, $T_J = 70^\circ C$)

| Macro Type | Description | Max. t_{DLH} | Max. t_{DHL} | Max. t_{ENZH} | Max. t_{ENZL} | Units |
|------------|---|-------------------|-------------------|--------------------|--------------------|-------|
| OTB33PH | 3.3V, PCI Output Current, High Slew Rate | 4.20 | 4.47 | 4.23 | 3.85 | ns |
| OTB33PN | 3.3V, PCI Output Current, Nominal Slew Rate | 5.22 | 6.96 | 5.28 | 6.27 | ns |
| OTB33PL | 3.3V, PCI Output Current, Low Slew Rate | 6.30 | 8.61 | 6.37 | 7.93 | ns |
| OTB33LH | 3.3V, Low Output Current, High Slew Rate | 6.26 | 6.76 | 6.33 | 5.94 | ns |
| OTB33LN | 3.3V, Low Output Current, Nominal Slew Rate | 7.70 | 10.80 | 7.78 | 10.38 | ns |
| OTB33LL | 3.3V, Low Output Current, Low Slew Rate | 9.18 | 14.15 | 9.26 | 13.78 | ns |
| OTB25HH | 2.5V, High Output Current, High Slew Rate | 7.65 | 3.95 | 7.70 | 3.62 | ns |
| OTB25HN | 2.5V, High Output Current, Nominal Slew Rate | 8.77 | 6.24 | 8.85 | 5.87 | ns |
| OTB25HL | 2.5V, High Output Current, Low Slew Rate | 10.34 | 7.74 | 10.42 | 7.32 | ns |
| OTB25LH | 2.5V, Low Output Current, High Slew Rate | 13.43 | 5.71 | 13.46 | 5.30 | ns |
| OTB25LN | 2.5V, Low Output Current, Nominal Slew Rate | 14.74 | 9.73 | 14.81 | 9.39 | ns |
| OTB25LL | 2.5V, Low Output Current, Low Slew Rate | 16.17 | 12.86 | 16.23 | 12.51 | ns |
| OTB25LPHH | 2.5V, Low Power, High Output Current, High Slew Rate | 5.40 | 6.02 | 5.43 | 5.21 | ns |
| OTB25LPHN | 2.5V, Low Power, High Output Current, Nominal Slew Rate | 7.15 | 9.99 | 7.20 | 9.34 | ns |
| OTB25LPHL | 2.5V, Low Power, High Output Current, Low Slew Rate | 8.83 | 12.82 | 8.87 | 12.24 | ns |
| OTB25LPLH | 2.5V, Low Power, Low Output Current, High Slew Rate | 8.30 | 9.28 | 8.35 | 8.24 | ns |
| OTB25LPLN | 2.5V, Low Power, Low Output Current, Nominal Slew Rate | 10.44 | 15.38 | 10.49 | 14.92 | ns |
| OTB25LPLL | 2.5V, Low Power, Low Output Current, Low Slew Rate | 12.62 | 20.63 | 12.66 | 20.18 | ns |

Notes:

1. t_{DLH} = Data-to-Pad HIGH
2. t_{DHL} = Data-to-Pad LOW
3. t_{ENZH} = Enable-to-Pad, Z to HIGH
4. t_{ENZL} = Enable-to-Pad, Z to LOW

**Figure 15 • Output Buffer Delays****Table 2 • Output Buffer Delays (Worst-Case Commercial Conditions, $V_{DDP} = 3.0V$, $V_{DDL} = 2.3V$, $35pF$ load, $T_J = 70^{\circ}C$)**

| Macro Type | Description | Max. t_{DLH} | Max. t_{DHL} | Units |
|------------|---|----------------|----------------|-------|
| OB33PH | 3.3V, PCI Output Current, High Slew Rate | 4.20 | 4.47 | ns |
| OB33PN | 3.3V, PCI Output Current, Nominal Slew Rate | 5.22 | 6.96 | ns |
| OB33PL | 3.3V, PCI Output Current, Low Slew Rate | 6.30 | 8.61 | ns |
| OB33LH | 3.3V, Low Output Current, High Slew Rate | 6.26 | 6.76 | ns |
| OB33LN | 3.3V, Low Output Current, Nominal Slew Rate | 7.70 | 10.80 | ns |
| OB33LL | 3.3V, Low Output Current, Low Slew Rate | 9.18 | 14.15 | ns |
| OB25HH | 2.5V, High Output Current, High Slew Rate | 7.65 | 3.95 | ns |
| OB25HN | 2.5V, High Output Current, Nominal Slew Rate | 8.77 | 6.24 | ns |
| OB25HL | 2.5V, High Output Current, Low Slew Rate | 10.34 | 7.74 | ns |
| OB25LH | 2.5V, Low Output Current, High Slew Rate | 13.43 | 5.71 | ns |
| OB25LN | 2.5V, Low Output Current, Nominal Slew Rate | 14.74 | 9.73 | ns |
| OB25LL | 2.5V, Low Output Current, Low Slew Rate | 16.17 | 12.86 | ns |
| OB25LPHH | 2.5V, Low Power, High Output Current, High Slew Rate | 5.40 | 6.02 | ns |
| OB25LPHN | 2.5V, Low Power, High Output Current, Nominal Slew Rate | 7.15 | 9.99 | ns |
| OB25LPHL | 2.5V, Low Power, High Output Current, Low Slew Rate | 8.83 | 12.82 | ns |
| OB25LPLH | 2.5V, Low Power, Low Output Current, High Slew Rate | 8.30 | 9.28 | ns |
| OB25LPLN | 2.5V, Low Power, Low Output Current, Nominal Slew Rate | 10.44 | 15.38 | ns |
| OB25LPLL | 2.5V, Low Power, Low Output Current, Low Slew Rate | 12.62 | 20.63 | ns |

Notes:

1. t_{DLH} = Data-to-Pad HIGH
2. t_{DHL} = Data-to-Pad LOW

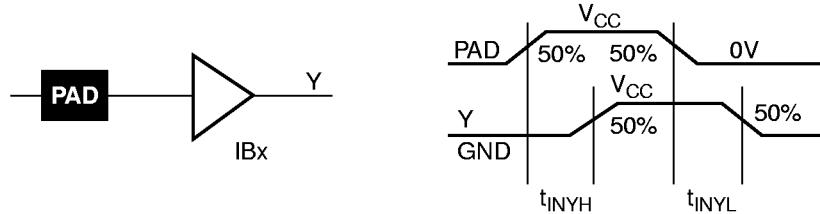


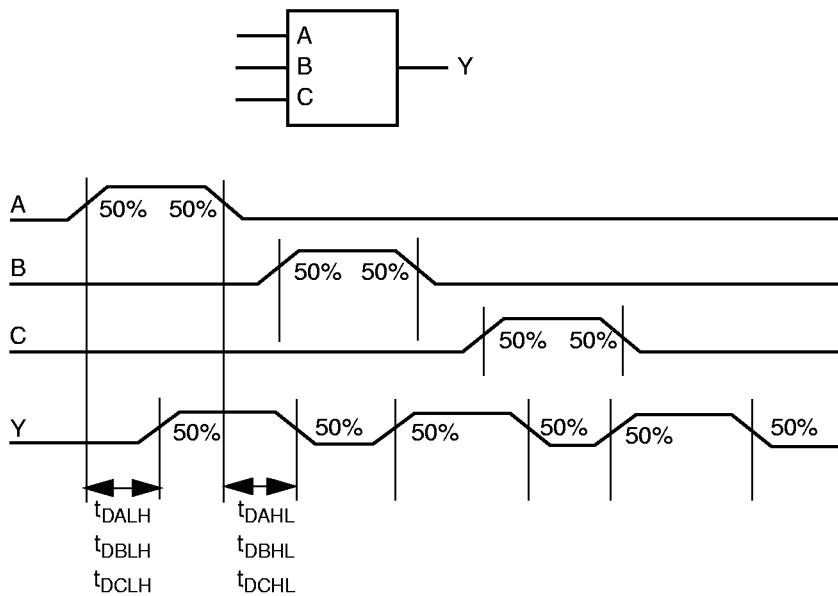
Figure 16 • Input Buffer Delays

Table 3 • Input Buffer Delays (Worst-Case Commercial Conditions, $V_{DDP} = 3.0V$, $V_{DDL} = 2.3V$, $35pF$ load, $T_J = 70^{\circ}C$)

| Macro Type | Description | Max. t_{IHYH} | Max. t_{INYL} | Units |
|------------|--|--------------------|--------------------|-------|
| IB25 | 2.5V, CMOS Input Levels, No Pull-up Resistor | 2.25 | 0.59 | ns |
| IB25LP | 2.5V, CMOS Input Levels, Low Power | 3.10 | 1.47 | ns |
| IB33 | 3.3V, CMOS Input Levels, No Pull-up Resistor | 2.14 | 0.99 | ns |

Notes:

1. t_{INYH} = Input Pad-to-Y HIGH
2. t_{INYL} = Input Pad-to-Y LOW

**Figure 17 • Module Delays****Table 4 • Sample Macrocell Library Listing (Worst-Case Commercial Conditions, $V_{DDL} = 2.3V$, $35pF$ load, $T_J = 70^\circ C$)**

| Cell Name | Description | Maximum Intrinsic Delay | Minimum Setup/Hold | Units |
|-----------|--|-------------------------|-------------------------------------|-------|
| NAND2 | 2-Input NAND | 0.42 | | ns |
| AND2 | 2-Input AND | 0.40 | | ns |
| NOR3 | 3-Input NOR | 0.42 | | ns |
| MUX2L | 2-1 Mux with Active Low Select | 0.42 | | ns |
| OA21 | 2-Input OR into a 2-Input AND | 0.40 | | ns |
| XOR2 | 2-Input Exclusive OR | 0.34 | | ns |
| LDL | Active Low Latch (LH HL) | D: 0.26/0.21 | t_{setup} 0.54 t_{hold} 0.20 | ns |
| DFFL | Negative Edge-Triggered D-type Flip-Flop (LH HL) | CLK-Q: 0.42/0.37 | t_{setup} 0.43 t_{hold} 0.20 | ns |

Note: Assumes two standard loads.

Embedded Memory Specifications

This section focuses on the embedded memory of the ProASIC 500K family. It describes the SRAM and FIFO interface signals and includes timing diagrams that show the relationships of signals as they pertain to single embedded memory blocks. See Table 5.

Enclosed Timing Diagrams—SRAM Mode:

- Asynchronous RAM Read, Address Controlled, RDB=0
- Asynchronous RAM Read, RDB Controlled
- Asynchronous RAM Write

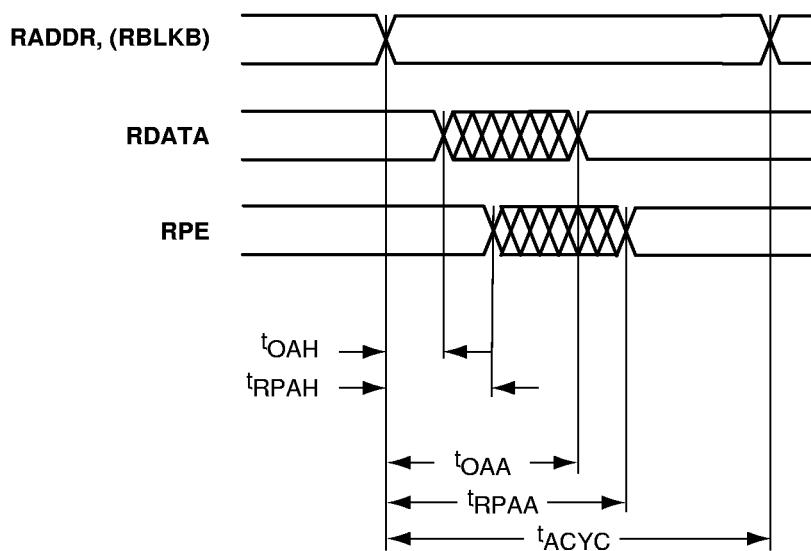
- Synchronous RAM Read, Access Timed Output Strobe
- Synchronous RAM Read, Pipeline Mode Outputs
- Synchronous RAM Write
- Synchronous Write & Read to the Same Location
- Asynchronous Write & Synchronous Read to the Same Location
- Asynchronous Write & Read to the Same Location
- Synchronous Write & Asynchronous Read to the Same Location

Table 5 • Memory Block SRAM Interface Signals

| SRAM Signal | Hookup | Bits | In/Out | Description |
|-------------|----------------|------|--------|---|
| WCLKS | Route | 1 | IN | Write clock used on synchronization on write side |
| RCLKS | Route | 1 | IN | Read clock used on synchronization on read side |
| RADDR<0:7> | Route | 8 | IN | Read address. |
| RBLKB | Route/ Config. | 1 | IN | Negative true read block select. |
| RDB | Route/ Config. | 1 | IN | Negative true read pulse. |
| WADDR<0:7> | Route | 8 | IN | Write address. |
| WBLKB | Route/ Config. | 1 | IN | Negative true write block select. |
| DI<0:8> | Route | 9 | IN | Input data bits <0:8>, <8> will be generated if PARGEN is true. |
| WRB | Route | 1 | IN | Negative true write pulse. |
| DO<0:8> | Route | 9 | OUT | Output data bits <0:8> |
| RPE | Route | 1 | OUT | Read parity error. |
| WPE | Route | 1 | OUT | Write parity error. |
| PARODD | Config. | 1 | IN | Selects odd parity generation/detect when high, even when low. |

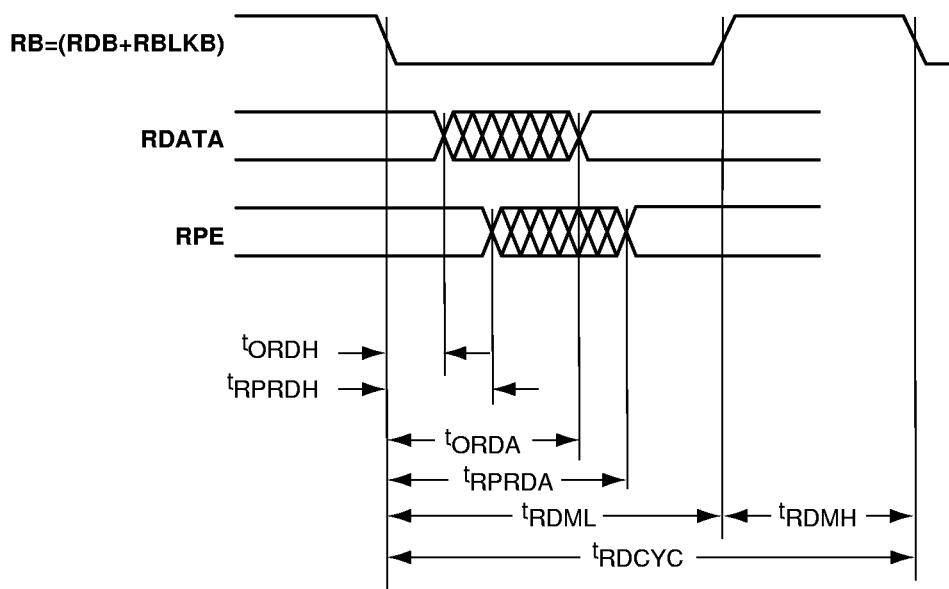
Notes: Not all signals shown are used in all modes.

Config. = Configurable

Asynchronous RAM Read, Address Controlled, RDB=0

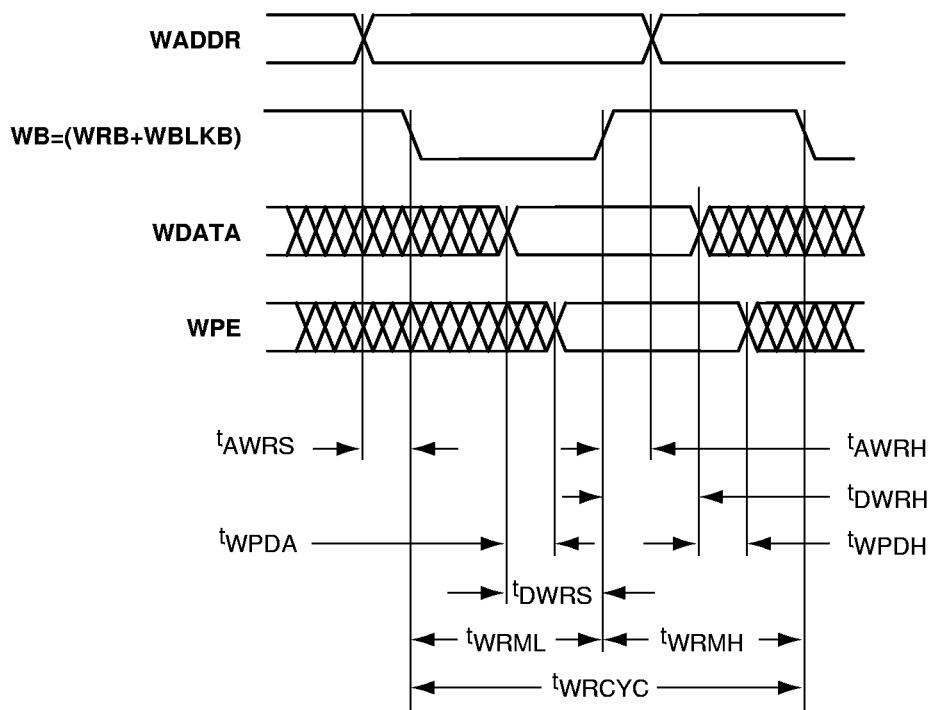
T_J = 0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t _{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------------|-----------------------------------|------|------|-------|-------|
| ACYC | Read cycle time | 7.5 | | ns | |
| OAA | New RDAT access from RADDR stable | 7.5 | | ns | |
| OAH | Old RDAT hold from RADDR stable | | 3.0 | ns | |
| RPAA | New RPE access from RADDR stable | 10.0 | | ns | |
| RPAH | Old RPE hold from RADDR stable | | 3.0 | ns | |

Asynchronous RAM Read, RDB Controlled


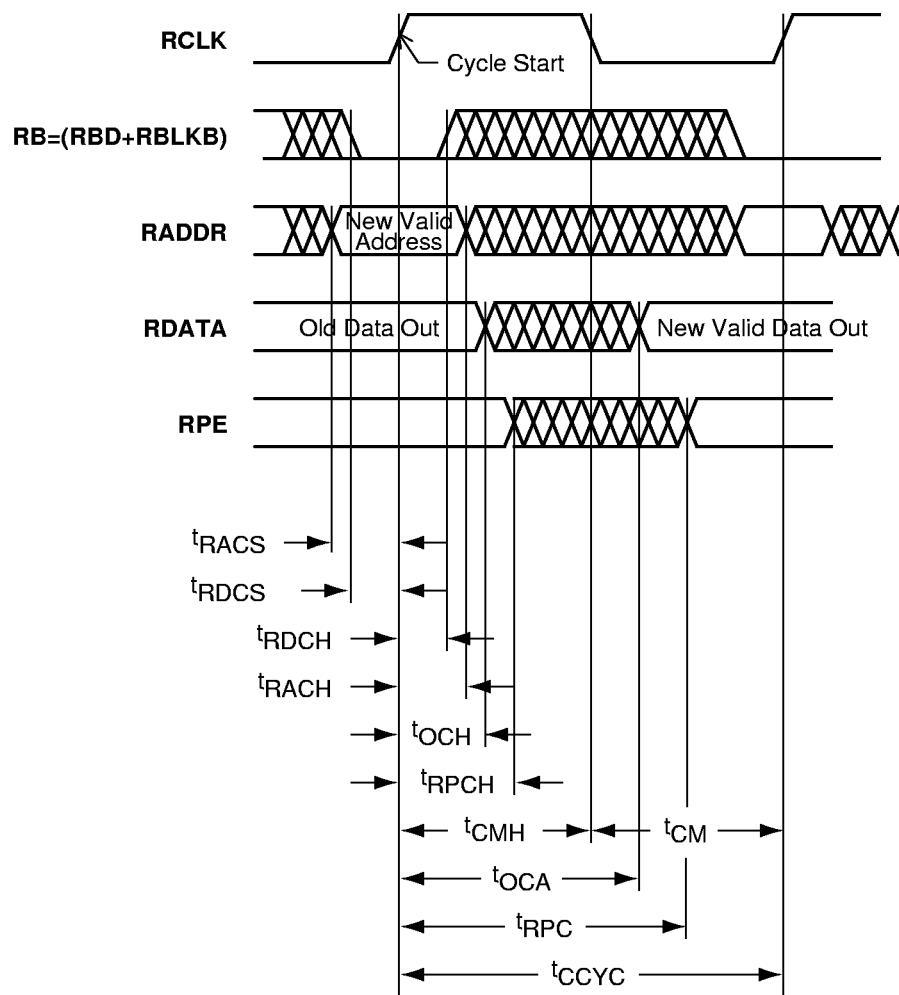
$T_J = 0^\circ\text{C} \text{ to } 110^\circ\text{C}; V_{DDL} = 2.30\text{V} \text{ to } 2.70\text{V}$

| Symbol t_{xxx} | Description | Min. | Max. | Units | Notes |
|------------------|----------------------------|------|------|-------|-----------------------------|
| ORDA | New RDATA access from RB ↓ | 7.5 | | ns | |
| ORDH | Old RDATA valid from RB ↓ | | 3.0 | ns | |
| RDCYC | Read cycle time | 7.5 | | ns | |
| RDMH | RB high phase | 3.0 | | ns | Inactive setup to new cycle |
| RDML | RB low phase | 3.0 | | ns | Active |
| RPRDA | New RPE access from RB ↓ | 9.5 | | ns | |
| RPRDH | Old RPE valid from RB ↓ | | 3.0 | ns | |

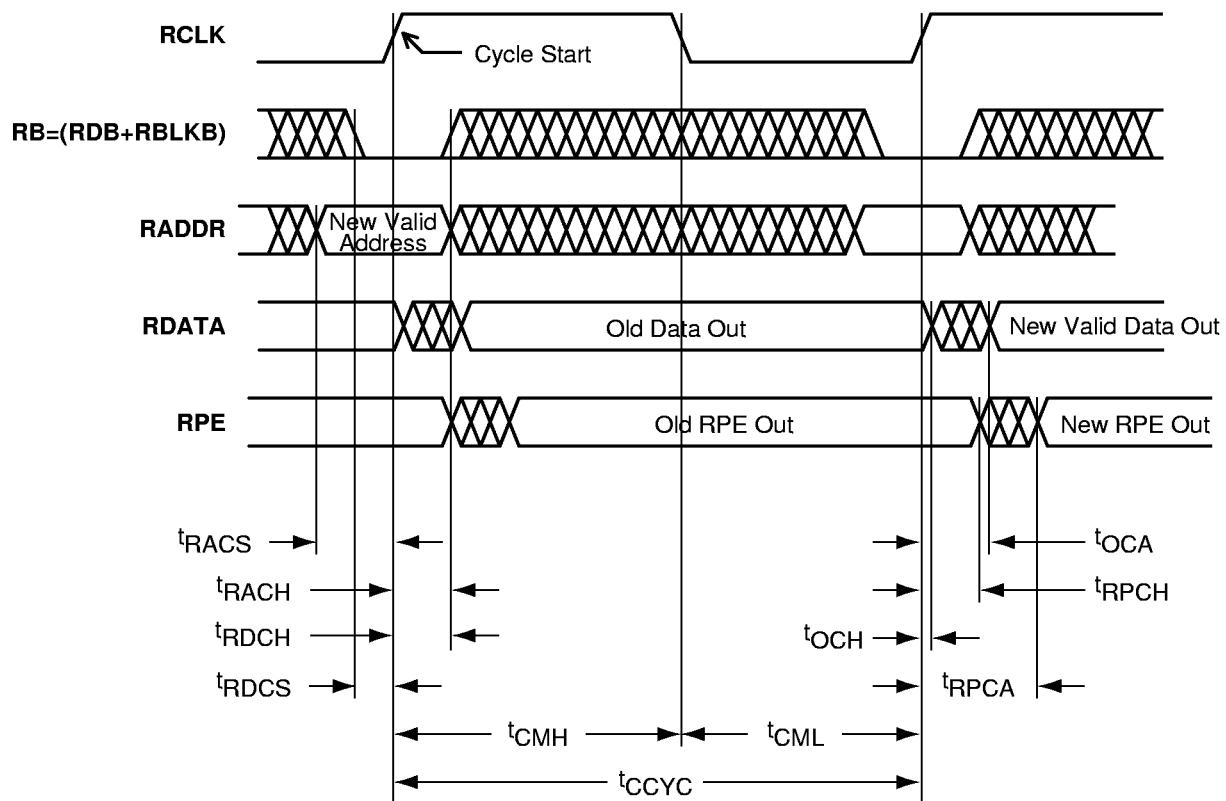
Asynchronous RAM Write

$T_J = 0^\circ\text{C}$ to 110°C ; $V_{DDL} = 2.30\text{V}$ to 2.70V

| Symbol t_{xxx} | Description | Min. | Max. | Units | Notes |
|------------------|--------------------------------|------|------|-------|----------------------|
| AWRH | WADDR hold from WB \uparrow | 1.0 | | ns | |
| AWRS | WADDR setup to WB \downarrow | 0.5 | | ns | |
| DWRH | WDATA hold from WB \uparrow | 1.5 | | ns | |
| DWRS | WDATA setup to WB \uparrow | 0.5 | | ns | PARGEN is inactive. |
| DWRS | WDATA setup to WB \uparrow | 2.5 | | ns | PARGEN is active. |
| WPDA | WPE access from WDATA | 3.0 | | ns | WPE is invalid while |
| WPDH | WPE hold from WDATA | | 1.0 | ns | PARGEN is active. |
| WRCYC | Cycle time | 7.5 | | ns | |
| WRMH | WB high phase | 3.0 | | ns | Inactive |
| WRML | WB low phase | 3.0 | | ns | Active |

Synchronous RAM Read, Access Timed Output Strobe

 $T_J = 0^\circ\text{C}$ to 110°C ; $V_{DDL} = 2.30\text{V}$ to 2.70V

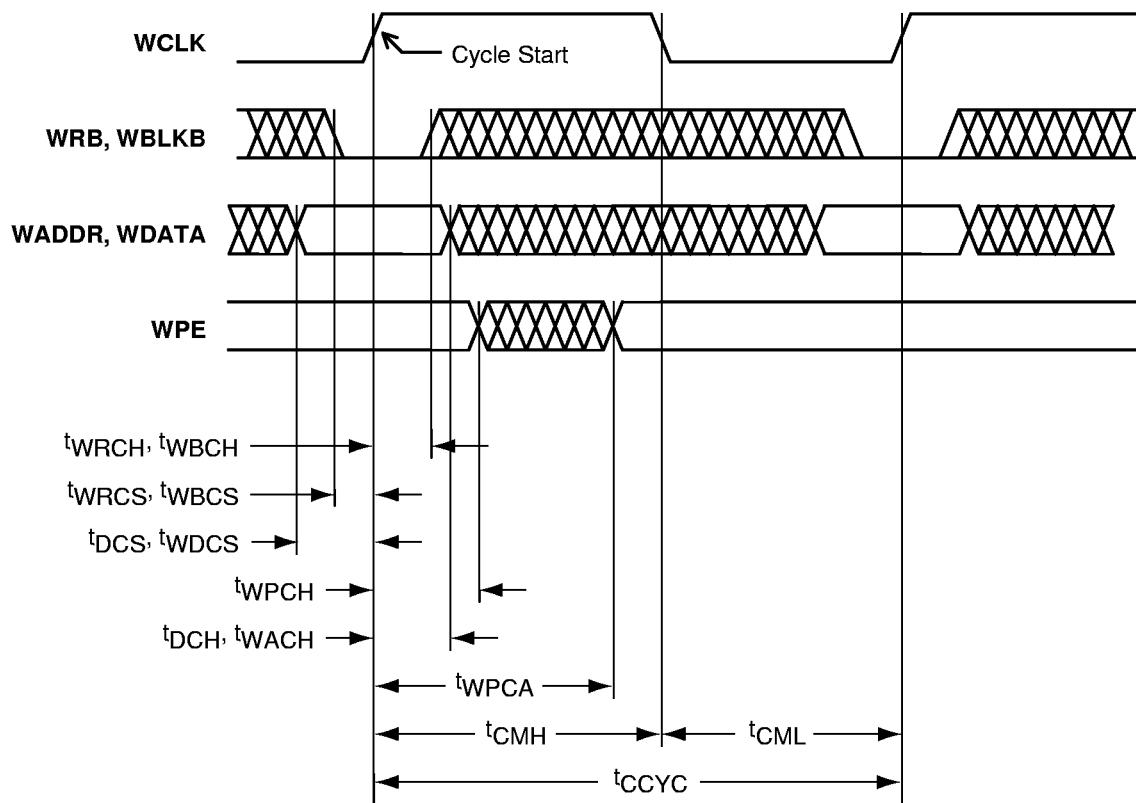
| Symbol t_{xxx} | Description | Min. | Max. | Units | Notes |
|------------------|--------------------------------------|------|------|-------|-------|
| CCYC | Cycle time | 7.5 | | ns | |
| CMH | Clock high phase | 3.0 | | ns | |
| CML | Clock low phase | 3.0 | | ns | |
| OCA | New RDATA access from CLK \uparrow | 7.5 | | ns | |
| OCH | Old RDATA valid from CLK \uparrow | | 3.0 | ns | |
| RACH | RADDR hold from CLK \uparrow | 0.5 | | ns | |
| RACS | RADDR setup to CLK \uparrow | 1.0 | | ns | |
| RDCH | RDB hold from CLK \uparrow | 0.5 | | ns | |
| RDCH | RDB hold from CLK \uparrow | 0.5 | | ns | |
| RDCS | RDB setup to CLK \uparrow | 1.0 | | ns | |
| RPCA | New RPE access from CLK \uparrow | 9.5 | | ns | |
| RPCH | Old RPE valid from CLK \uparrow | | 3.0 | ns | |

Synchronous RAM Read, Pipeline Mode Outputs

T_J = 0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t _{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------------|-----------------------------|------|------|-------|-------|
| CCYC | Cycle time | 7.5 | | ns | |
| CMH | Clock high phase | 3.0 | | ns | |
| CML | Clock low phase | 3.0 | | ns | |
| OCA | New RDATA access from CLK ↑ | 2.0 | | ns | |
| OCH | Old RDATA valid from CLK ↑ | | .75 | ns | |
| RACH | RADDR hold from CLK ↑ | 0.5 | | ns | |
| RACS | RADDR setup to CLK ↑ | 1.0 | | ns | |
| RDCH | RDB hold from CLK ↑ | 0.5 | | ns | |
| RDGS | RDB setup to CLK ↑ | 1.0 | | ns | |
| RPCA | New RPE access from CLK ↑ | 4.0 | | ns | |
| RPCH | Old RPE valid from CLK ↑ | | 1.0 | ns | |

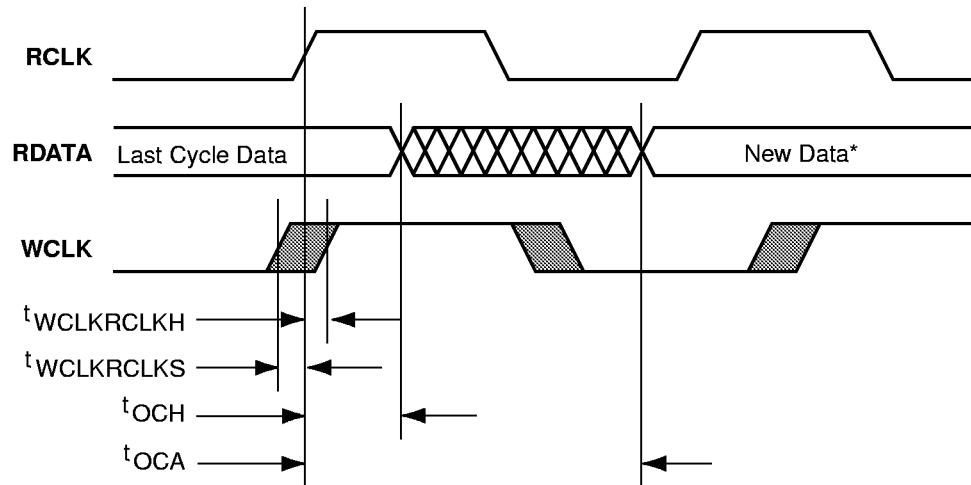
Synchronous RAM Write



T_J = 0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t_{xxx} | Description | Min. | Max. | Units | Notes |
|------------------|-----------------------------|------|------|-------|--|
| CCYC | Cycle time | 7.5 | | ns | |
| CMH | Clock high phase | 3.0 | | ns | |
| CML | Clock low phase | 3.0 | | ns | |
| DCH | WDATA hold from CLK ↑ | 0.5 | | ns | |
| DCS | WDATA setup to CLK ↑ | 1.0 | | ns | |
| WACH | WADDR hold from CLK ↑ | 0.5 | | ns | |
| WACS | WADDR setup to CLK ↑ | 1.0 | | ns | |
| WPCA | New WPE access from CLK ↑ | 3.0 | | ns | WPE is invalid while PARGEN is active. |
| WPCH | Old WPE valid from CLK ↑ | | 0.5 | ns | |
| WRCH, WBCH | WRB & WBLKB hold from CLK ↑ | 0.5 | | ns | |
| WRCS, WBCS | WRB & WBLKB setup to CLK ↑ | 1.0 | | ns | |

Note: On simultaneous read and write accesses to the same location WDATA is output to RDATA

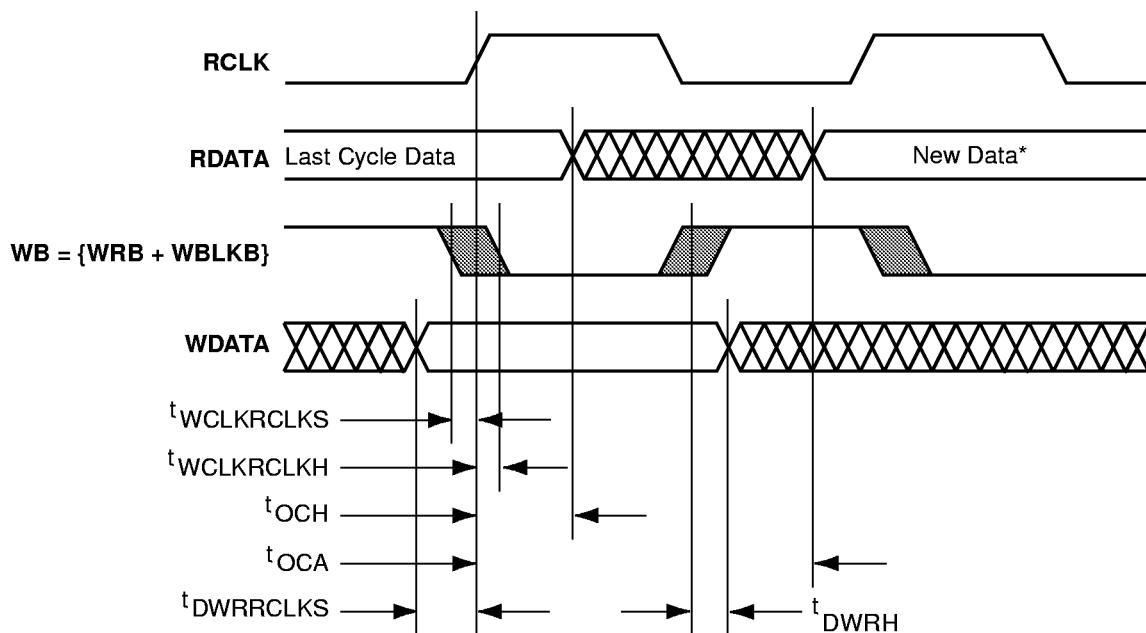
Synchronous Write & Read to the Same Location

* New data is read if WCLK \uparrow occurs before setup time.
The data stored is read if WCLK \uparrow occurs after hold time.

T_J=0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t_{xxx} | Description | Min. | Max. | Units | Notes |
|------------------|---|------|------|-------|---|
| CCYC | Cycle time | 7.5 | | ns | |
| CMH | Clock high phase | 3.0 | | ns | |
| CML | Clock low phase | 3.0 | | ns | |
| WCLKRCLKS | WCLK \uparrow to RCLK \uparrow setup time | -0.1 | | ns | |
| WCLKRCLKH | WCLK \uparrow to RCLK \uparrow hold time | | 7.0 | ns | |
| OCH | Old RDATA valid from RCLK \uparrow | | 3.0 | ns | OCA/OCH displayed for Access Timed Output |
| OCA | New RDATA valid from RCLK \uparrow | 7.5 | | ns | |

1. This behavior is valid for Access Timed Output and Pipelined Mode Output. Shown are the timings of an Access Timed Output.
2. During synchronous write and synchronous read access to the same location, the new write data will be read out if the active write clock edge occurs before or at the same time as the active read clock edge. The negative setup time insures this behavior for WCLK and RCLK driven by the same design signal.
3. If WCLK changes after the hold time, the data will be read.
4. A setup or hold time violation will result in unknown output data.

Asynchronous Write & Synchronous Read to the Same Location


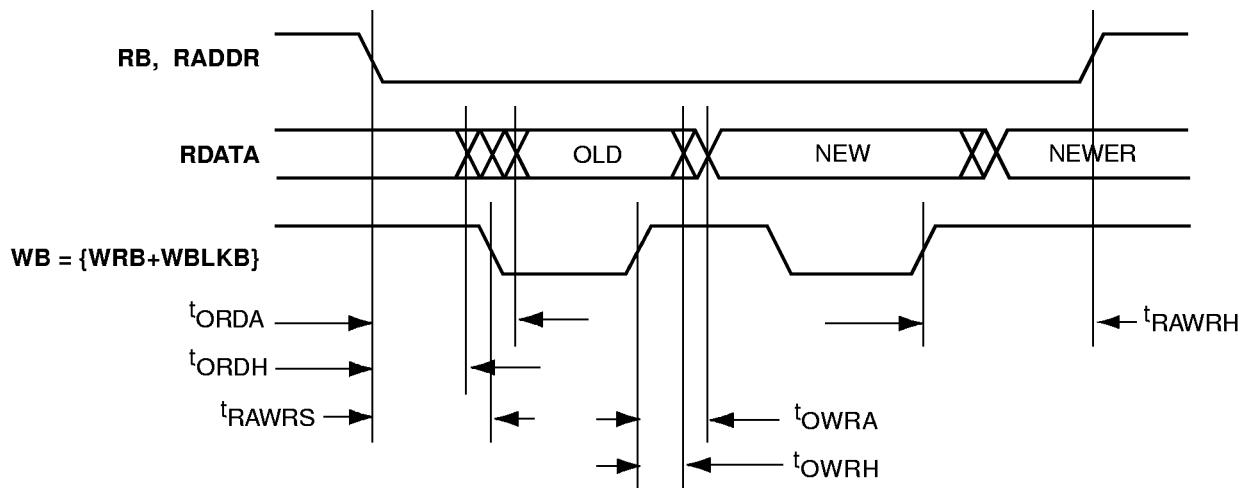
* New data is read if $WB \downarrow$ occurs before setup time.

The stored data is read if $WB \downarrow$ occurs after hold time.

T_J=0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t_{xxx} | Description | Min. | Max. | Units | Notes |
|------------------|---|------|------|-------|---|
| CCYC | Cycle time | 7.5 | | ns | |
| CMH | Clock high phase | 3.0 | | ns | |
| CML | Clock low phase | 3.0 | | ns | |
| WBRCLKS | WB \downarrow to RCLK \uparrow setup time | -0.1 | | ns | |
| WBRCLKH | WB \downarrow to RCLK \uparrow hold time | | 7.0 | ns | |
| OCH | Old RDATA valid from RCLK \uparrow | | 3.0 | ns | OCA/OCH displayed for Access Timed Output |
| OCA | New RDATA valid from RCLK \uparrow | 7.5 | | ns | |
| DWRRCLKS | WDATA to RCLK \uparrow setup time | 0 | | ns | |
| DWRH | WDATA to WB \uparrow hold time | | 1.5 | ns | |

1. This behavior is valid for Access Timed Output and Pipelined Mode Output. Shown are the timings of an Access Timed Output.
2. In asynchronous write and synchronous read access to the same location, the new write data will be read out if the active write signal edge occurs before or at the same time as the active read clock edge. If WB changes to low after hold time, the data will be read.
3. A setup or hold time violation will result in unknown output data.

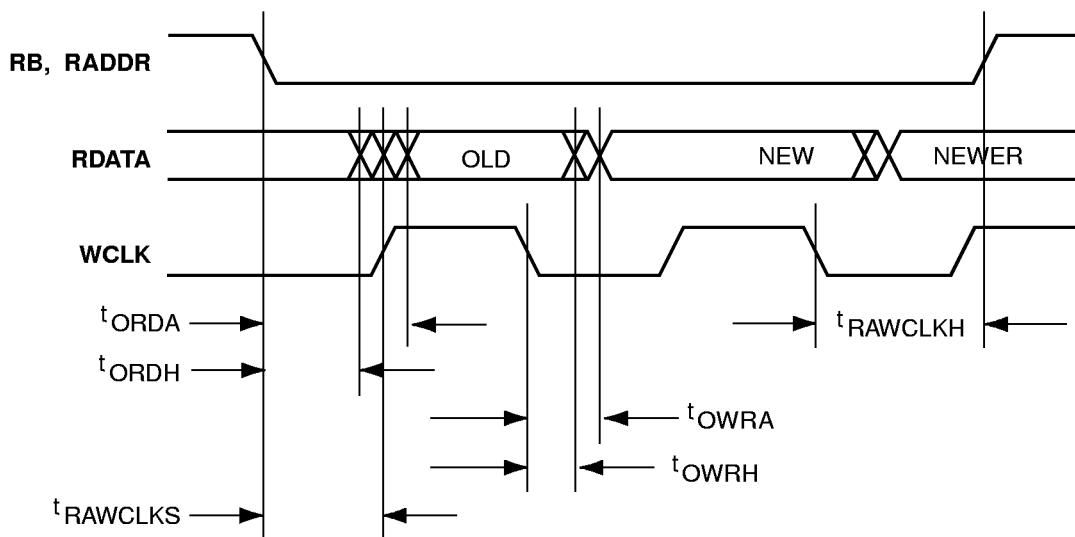
Asynchronous Write & Read to the Same Location

T_J=0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t _{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------------|----------------------------|------|------|-------|-------|
| ORDA | New RDATA access from RB ↓ | 7.5 | | ns | |
| ORDH | Old RDATA valid from RB ↓ | | 3.0 | ns | |
| OWRA | New RDATA access from WB ↑ | 3.0 | | ns | |
| OWRH | Old RDATA valid from WB ↑ | | 0.5 | ns | |
| RAWRS | RB ↓ or RADDR from WB ↓ | 5.0 | | ns | |
| RAWRH | RB ↑ or RADDR from WB ↑ | 5.0 | | ns | |

1. During an asynchronous read cycle, each write operation (sync. or async.) to the same location will automatically trigger a read operation which updates the read data.
2. Violation or RAWRS will disturb access to the OLD data.
3. Violation of RAWRH will disturb access to the NEWER data.

Synchronous Write & Asynchronous Read to the Same Location



T_J=0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t _{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------------|------------------------------|------|------|-------|-------|
| ORDA | New RDATA access from RB ↓ | 7.5 | | ns | |
| ORDH | Old RDATA valid from RB ↓ | | 3.0 | ns | |
| OWRA | New RDATA access from WCLK ↓ | 3.0 | | ns | |
| OWRH | Old RDATA valid from WCLK ↓ | | 0.5 | ns | |
| RAWCLKS | RB ↓ or RADDR from WCLK ↑ | 5.0 | | ns | |
| RAWCLKH | RB ↑ or RADDR from WCLK ↓ | 5.0 | | ns | |

1. During an asynchronous read cycle, each write operation (sync. or async.) to the same location will automatically trigger a read operation which updates the read data.
2. Violation of RAWCLKS will disturb access to OLD data.
3. Violation of RAWCLKH will disturb access to NEWER data.

Asynchronous FIFO Full and Empty Transitions

The asynchronous FIFO accepts writes and reads while not full or not empty respectively. When the FIFO is full, all writes are inhibited. Conversely, when the FIFO is empty, all reads are inhibited. A problem is created if the FIFO is written during the transition out of full to not full or read during the transition out of empty to not empty. The exact time at which the write (read) operation changes from inhibited to accepted after the read (write) signal which causes the transition from Full (Empty) to not Full (Empty) is indeterminate. This indeterminate period starts 1ns after the RB (WB) transition which deactivates Full (Not Empty) and ends 3ns after the RB (WB) transition, for slow cycles.

For fast cycles, the indeterminate period ends 7.5ns—RDL (WRL) or 3ns after the RB (WB) transition whichever is later.

The timing diagram for write is shown in Figure 18. The timing diagram for read is shown in Figure 19.

Enclosed Timing Diagrams—FIFO Mode:

- Asynchronous FIFO Read
- Asynchronous FIFO Write
- Synchronous FIFO Read, Access Timed Output Strobe
- Synchronous FIFO Read, Pipeline Mode Outputs
- Synchronous FIFO Write
- FIFO Reset

Table 6 • Memory Block FIFO Interface Signals

| FIFO Signal | Hookup | Bits | In/Out | Description |
|-------------|---------------|------|--------|--|
| WCLKS | Route | 1 | IN | Write clock used on synchronization on write side |
| RCLKS | Route | 1 | IN | Read clock used on synchronization on read side |
| LEVEL <0:7> | Route/Config. | 8 | IN | Direct configuration implements static flag logic. |
| RBLKB | Route/Config. | 1 | IN | Negative true read block select. |
| RDB | Route/Config. | 1 | IN | Negative true read pulse. |
| RESET | Route | 1 | IN | Negative true reset for FIFO pointers. |
| WBLKB | Route/Config. | 1 | IN | Negative true write block select. |
| DI<0:8> | Route | 9 | IN | Input data bits <0:8>, <8> will be generated if PARGEN is true. |
| WRB | Route | 1 | IN | Negative true write pulse. |
| FULL, EMPTY | Route | 2 | OUT | FIFO flags. FULL prevents write and EMPTY prevents read. |
| EQTH, GEQTH | Route | 2 | OUT | EQTH is true when the FIFO holds (LEVEL) words. GEQTH is true when the FIFO holds (LEVEL) words or more. |
| DO<0:8> | Route | 9 | OUT | Output data bits <0:8> |
| RPE | Route | 1 | OUT | Read parity error. |
| WPE | Route | 1 | OUT | Write parity error. |
| LGDEP <0:2> | Config. | 3 | IN | Configures DEPTH of the FIFO to $2^{(LGDEP+1)}$ |
| PARODD | Config. | 1 | IN | Selects odd parity generation/detect when high, even when low. |

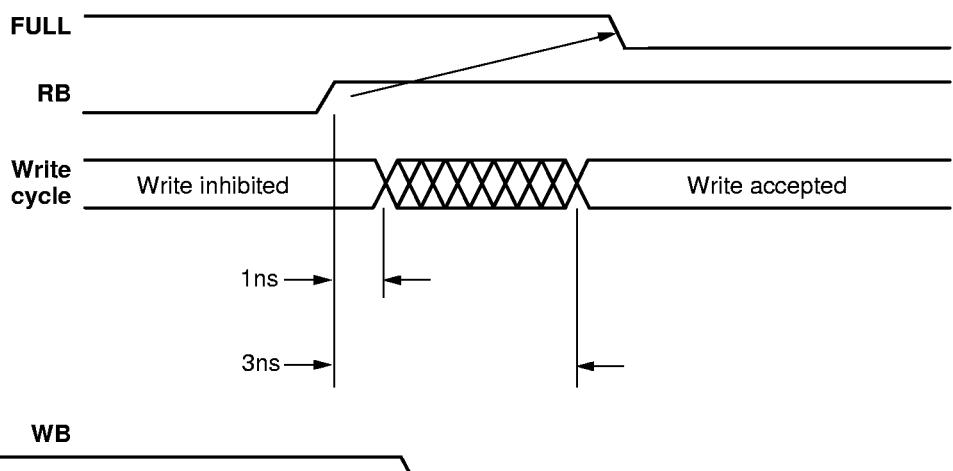


Figure 18 • Write Timing Diagram

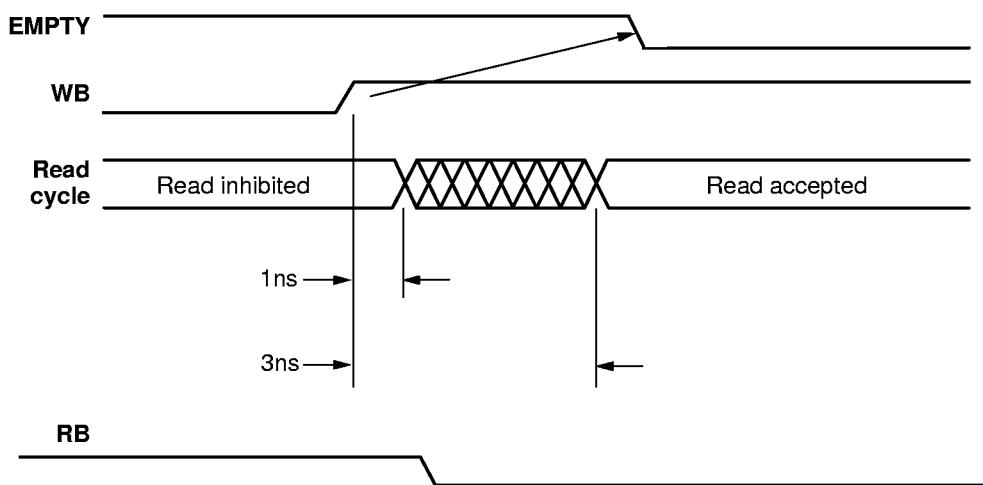
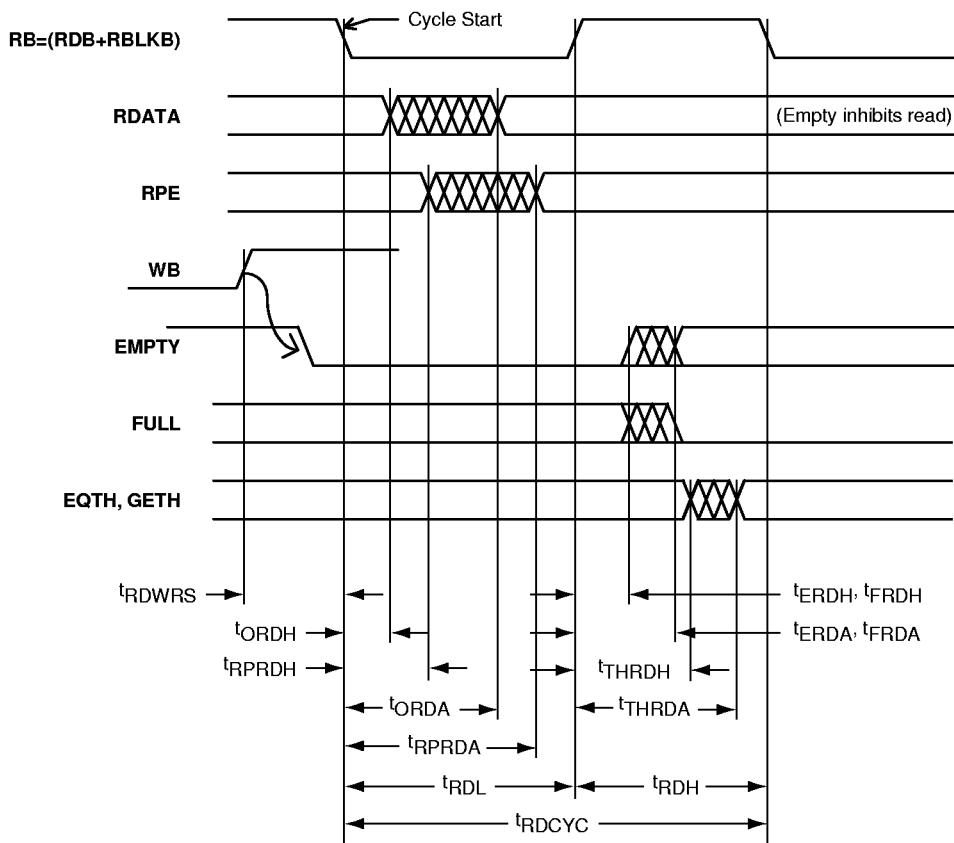


Figure 19 • Read Timing Diagram

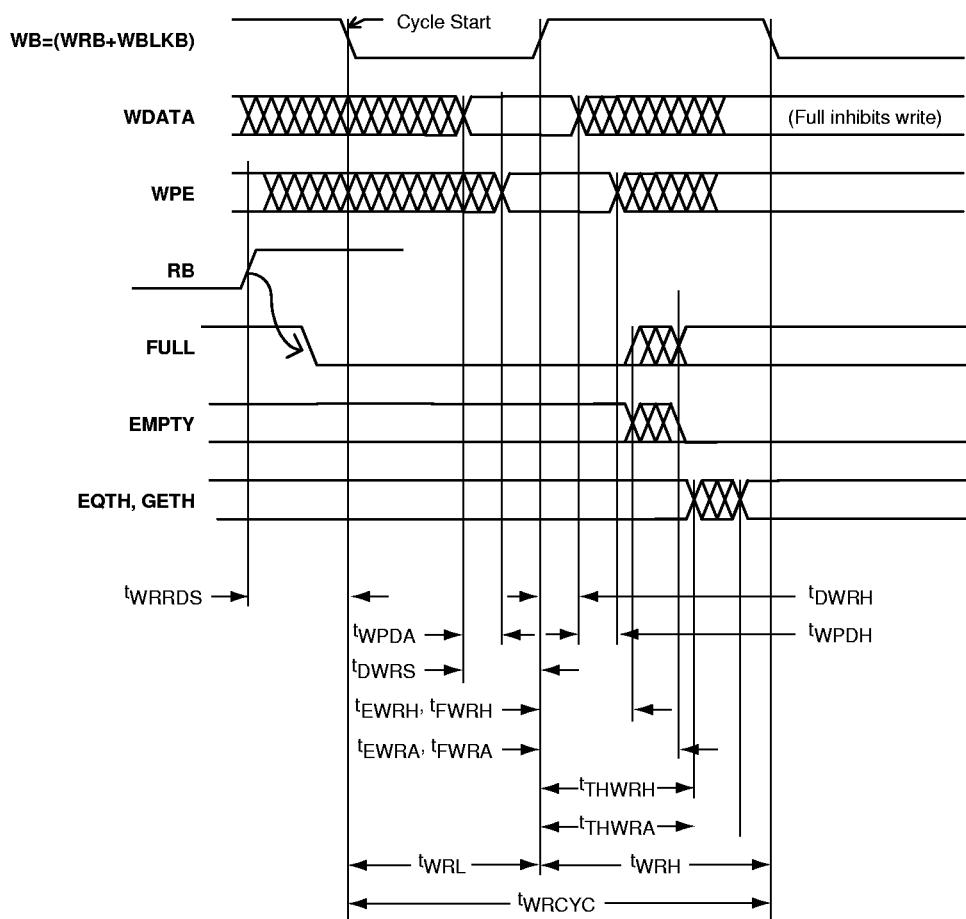
Asynchronous FIFO Read

T_J = 0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t _{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------------|---|-------|------|-------|--|
| ERDH, FRDH, THRDH | Old EMPTY, FULL, EQTH, & GETH valid hold time from RB ↑ | | 0.5 | ns | Empty/full/thresh are invalid from the end of hold until the new access is complete. |
| ERDA | New EMPTY access from RB ↑ | 3.0* | | ns | |
| FRDA | FULL↓ access from RB ↑ | 3.0* | | ns | |
| ORDA | New RDATA access from RB ↓ | 7.5 | | ns | |
| ORDH | Old RDATA valid from RB ↓ | | 3.0 | ns | |
| RDCYC | Read cycle time | 7.5 | | ns | |
| RDWRS | WB ↑, clearing EMPTY, setup to RB ↓ | 3.0** | | ns | Enabling the read operation. |
| | | | 1.0 | ns | Inhibiting the read operation. |
| RDH | RB high phase | 3.0 | | ns | Inactive |
| RDL | RB low phase | 3.0 | | ns | Active |
| RPRDA | New RPE access from RB ↓ | 9.5 | | ns | |
| RPRDH | Old RPE valid from RB ↓ | | 4.0 | ns | |
| THRDA | EQTH or GETH access from RB↑ | 4.5 | | ns | |

Notes: *At fast cycles, ERDA & FRDA

**At fast cycles, RDWRS (for enabling read) = MAX(7.5ns-WRL), 3.0ns

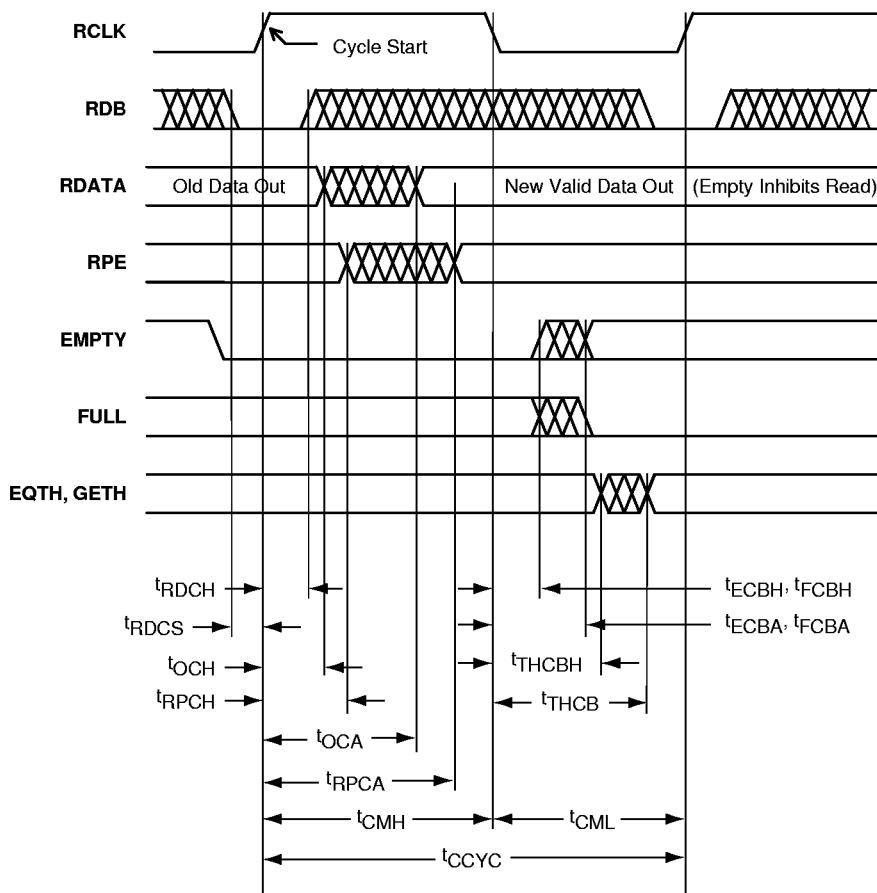
Asynchronous FIFO Write


T_J = 0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t _{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------------|--|-------|------|-------|--|
| DWRH | WDATA hold from WB ↑ | 1.5 | | ns | |
| DWRS | WDATA setup to WB ↑ | 0.5 | | ns | PARGEN is inactive. |
| DWRS | WDATA setup to WB ↑ | 2.5 | | ns | PARGEN is active. |
| EWRH, FWRH, THWRH | Old EMPTY, FULL, EQTH, & GETH valid hold time after WB ↑ | | 0.5 | ns | Empty/full/thresh are invalid from the end of hold until the new access is complete. |
| EWRA | EMPTY ↓ access from WB ↑ | 3.0* | | ns | |
| FWRA | New FULL access from WB ↑ | 3.0* | | ns | |
| THWRA | EQTH or GETH access from WB ↑ | 4.5 | | ns | |
| WPDA | WPE access from WDATA | 3.0 | | ns | WPE is invalid while PARGEN is active. |
| WPDH | WPE hold from WDATA | | 1.0 | ns | |
| WRCYC | Cycle time | 7.5 | | ns | |
| WRRDS | RB ↑, clearing FULL, setup to WB ↓ | 3.0** | | ns | Enabling the write operation. |
| | | | 1.0 | | Inhibiting the write operation. |
| WRH | WB high phase | 3.0 | | ns | Inactive |
| WRL | WB low phase | 3.0 | | ns | Active |

Notes: * At fast cycles, EWRA, FWRA = MAX((7.5ns-WRL), 3.0ns)

**At fast cycles, WWRDS (for enabling write) = MAX(7.5ns-RDL), 3.0ns

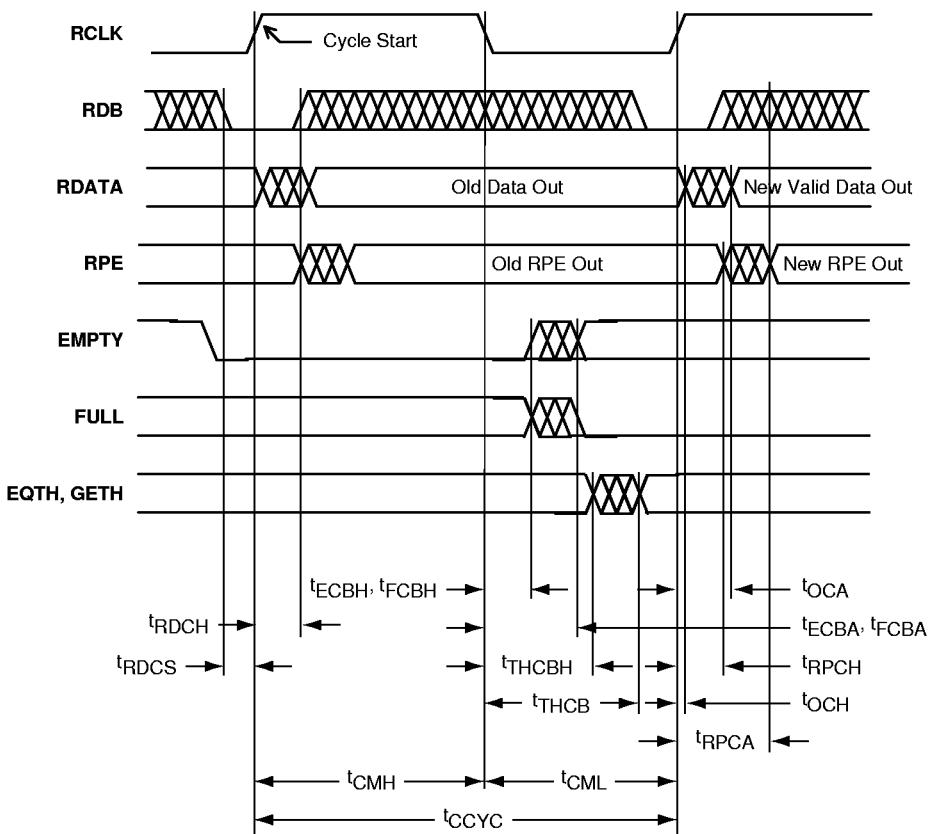
Synchronous FIFO Read, Access Timed Output Strobe

T_J = 0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t _{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------------|--|------|------|-------|--|
| CCYC | Cycle time | 7.5 | | ns | |
| CMH | Clock high phase | 3.0 | | ns | |
| CML | Clock low phase | 3.0 | | ns | |
| ECBA | New EMPTY access from CLK ↓ | 3.0* | | ns | |
| FCBA | FULL ↓ access from CLK ↓ | 3.0* | | ns | |
| ECBH, FCBH, THCBH | Old EMPTY, FULL, EQTH, & GETH valid hold time from CLK ↓ | | 1.0 | ns | Empty/full/thresh are invalid from the end of hold until the new access is complete. |
| OCA | New RDATa access from CLK ↑ | 7.5 | | ns | |
| OCH | Old RDATa valid from CLK ↑ | | 3.0 | ns | |
| RDCH | RDB hold from CLK ↑ | 0.5 | | ns | |
| RDCS | RDB setup to CLK ↑ | 1.0 | | ns | |
| RPCA | New RPE access from CLK ↑ | 9.5 | | ns | |
| RPCH | Old RPE valid from CLK ↑ | | 3.0 | ns | |
| THCBA | EQTH or GETH access from CLK ↓ | 4.5 | | ns | |

Note: *At fast cycles, ECBA & FCBA = MAX((7.5.ns-CMH), 3.0ns)

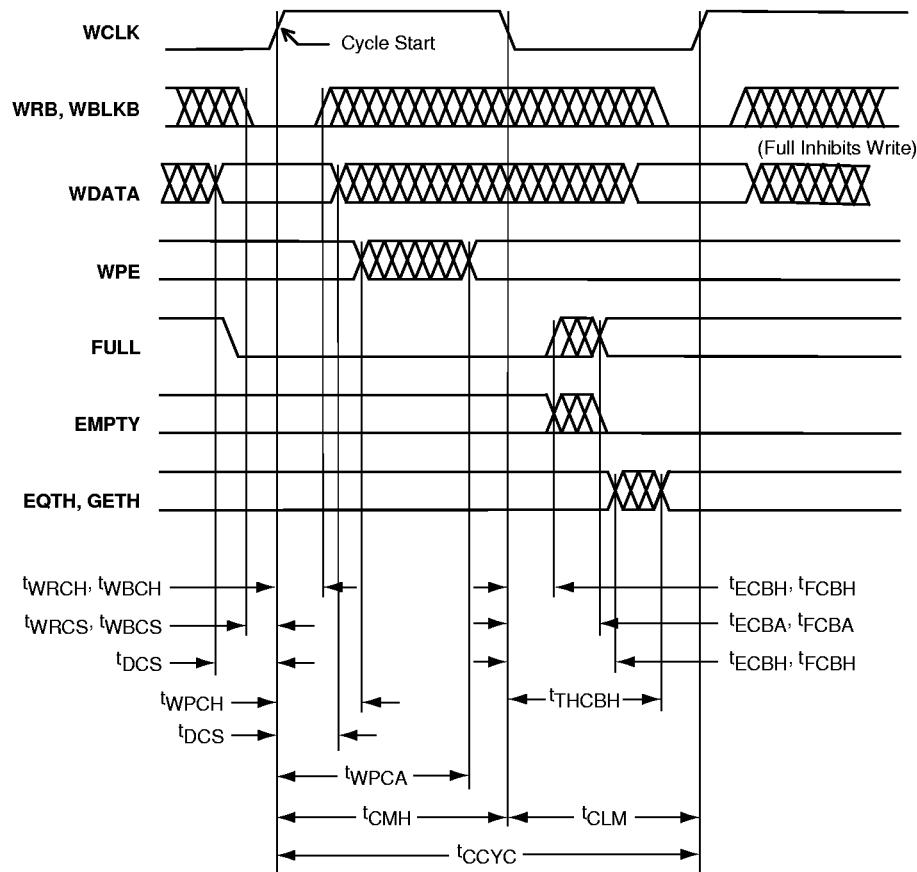
Synchronous FIFO Read, Pipeline Mode Outputs



T_J = 0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t _{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------------|--|------|------|-------|--|
| CCYC | Cycle time | 7.5 | | ns | |
| CMH | Clock high phase | 3.0 | | ns | |
| CML | Clock low phase | 3.0 | | ns | |
| ECBA | New EMPTY access from CLK ↓ | 3.0* | | ns | |
| FCBA | FULL ↓ access from CLK ↓ | 3.0* | | ns | |
| ECBH, FCBH, THCBH | Old EMPTY, FULL, EQTH, & GETH valid hold time from CLK ↓ | | 1.0 | ns | Empty/full/thresh are invalid from the end of hold until the new access is complete. |
| OCA | New RDATa access from CLK ↑ | 2.0 | | ns | |
| OCH | Old RDATa valid from CLK ↑ | | 0.75 | ns | |
| RDCH | RDB hold from CLK ↑ | 0.5 | | ns | |
| RDCS | RDB setup to CLK ↑ | 1.0 | | ns | |
| RPCA | New RPE access from CLK ↑ | 4.0 | | ns | |
| RPCH | Old RPE valid from CLK ↑ | | 1.0 | ns | |
| THCBA | EQTH or GETH access from CLK ↓ | 4.5 | | ns | |

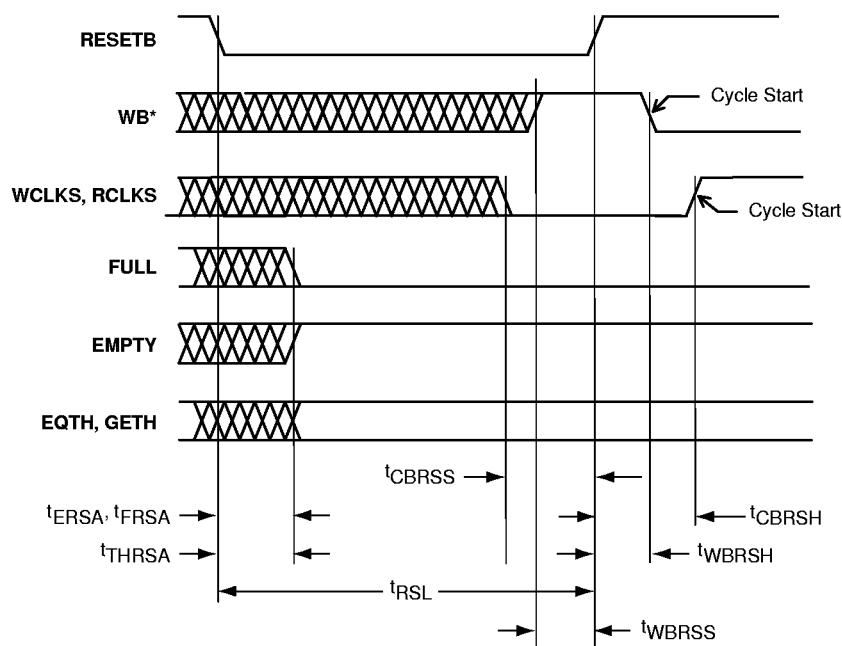
Note: *At fast cycles, ECBA & FCBA = MAX((7.5ns-CMS), 3.0ns)

Synchronous FIFO Write

T_J = 0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t_{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------|--|------|------|-------|--|
| CCYC | Cycle time | 7.5 | | ns | |
| CMH | Clock high phase | 3.0 | | ns | |
| CML | Clock low phase | 3.0 | | ns | |
| DCH | WDATA hold from CLK ↑ | 0.5 | | ns | |
| DCS | WDATA setup to CLK ↑ | 1.0 | | ns | |
| FCBA | New FULL access from CLK ↓ | 3.0* | | ns | |
| ECBA | EMPTY↓ access from CLK ↓ | 3.0* | | ns | |
| ECBH, FCBH, THCBH | Old EMPTY, FULL, EQTH, & GETH valid hold time from CLK ↓ | | 1.0 | ns | Empty/full/thresh are invalid from the end of hold until the new access is complete. |
| THCBA | EQTH or GETH access from CLK ↓ | 4.5 | | ns | |
| WPCA | New WPE access from CLK ↑ | 3.0 | | ns | WPE is invalid while PARGEN is active. |
| WPCH | Old WPE valid from CLK ↑ | | 0.5 | ns | |
| WRCH, WBCH | WRB & WBLKB hold from CLK ↑ | 0.5 | | ns | |
| WRCS, WBCS | WRB & WBLKB setup to CLK ↑ | 1.0 | | ns | |

Note: *At fast cycles, ECBA & FCBA = MAX((7.5ns-CMH), 3.0ns)

FIFO Reset


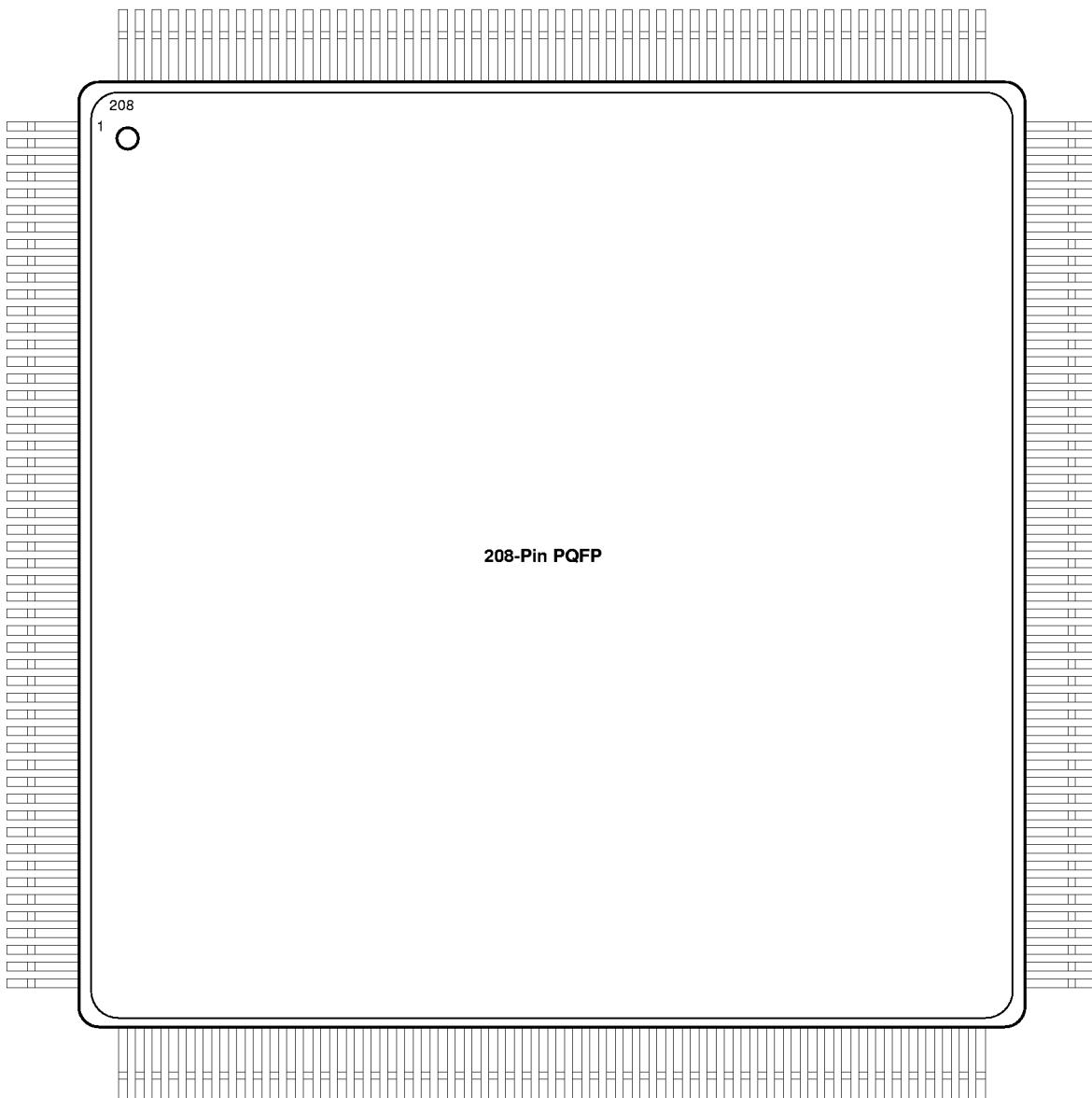
*WB = WRB + WBLRB

T_J = 0°C to 110°C; V_{DDL} = 2.30V to 2.70V

| Symbol t _{xxx} | Description | Min. | Max. | Units | Notes |
|-------------------------|--|------|------|-------|-------------------------|
| CBRSH | WCLKS or RCLKS \uparrow hold from RESETB \uparrow | 1.5 | | ns | Synchronous mode only. |
| CBRSS | WCLKS or RCLKS \downarrow setup to RESETB \uparrow | 1.5 | | ns | Synchronous mode only. |
| ERSA | New EMPTY \uparrow access from RESETB \downarrow | 3.0 | | ns | |
| FRSA | FULL \downarrow access from RESETB \downarrow | 3.0 | | ns | |
| RSL | RESETB low phase | 7.5 | | ns | |
| THRSA | EQTH or GETH access from RESETB \downarrow | 4.5 | | ns | |
| WBRSH | WB \downarrow hold from RESETB \uparrow | 1.5 | | ns | Asynchronous mode only. |
| WBRSS | WB \uparrow setup to RESETB \uparrow | 1.5 | | ns | Asynchronous mode only. |

Package Pin Assignments

208-Pin PQFP



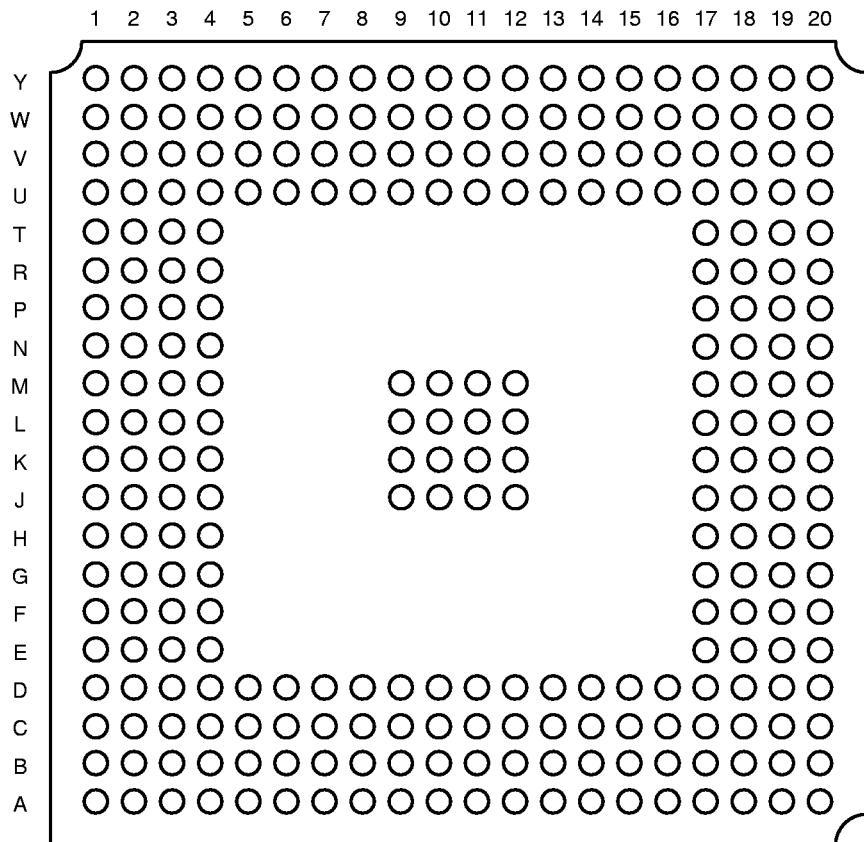
208-Pin PQFP

| Pin No. | A500K050 Function | A500K130 Function | A500K180 Function | A500K270 Function |
|---------|-------------------|-------------------|-------------------|-------------------|
| 1 | GND | GND | GND | GND |
| 2 | I/O | I/O | I/O | I/O |
| 3 | I/O | I/O | I/O | I/O |
| 4 | I/O | I/O | I/O | I/O |
| 5 | I/O | I/O | I/O | I/O |
| 6 | I/O | I/O | I/O | I/O |
| 7 | I/O | I/O | I/O | I/O |
| 8 | I/O | I/O | I/O | I/O |
| 9 | I/O | I/O | I/O | I/O |
| 10 | I/O | I/O | I/O | I/O |
| 11 | I/O | I/O | I/O | I/O |
| 12 | I/O | I/O | I/O | I/O |
| 13 | I/O | I/O | I/O | I/O |
| 14 | I/O | I/O | I/O | I/O |
| 15 | I/O | I/O | I/O | I/O |
| 16 | V _{DDL} | V _{DDL} | V _{DDL} | V _{DDL} |
| 17 | GND | GND | GND | GND |
| 18 | I/O | I/O | I/O | I/O |
| 19 | I/O | I/O | I/O | I/O |
| 20 | I/O | I/O | I/O | I/O |
| 21 | I/O | I/O | I/O | I/O |
| 22 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} |
| 23 | I/O | I/O | I/O | I/O |
| 24 | I/O | I/O | I/O | I/O |
| 25 | G1 | G1 | G1 | G1 |
| 26 | G0 | G0 | G0 | G0 |
| 27 | I/O | I/O | I/O | I/O |
| 28 | I/O | I/O | I/O | I/O |
| 29 | GND | GND | GND | GND |
| 30 | I/O | I/O | I/O | I/O |
| 31 | I/O | I/O | I/O | I/O |
| 32 | I/O | I/O | I/O | I/O |
| 33 | I/O | I/O | I/O | I/O |
| 34 | I/O | I/O | I/O | I/O |
| 35 | I/O | I/O | I/O | I/O |
| 36 | V _{DDL} | V _{DDL} | V _{DDL} | V _{DDL} |
| 37 | I/O | I/O | I/O | I/O |
| 38 | I/O | I/O | I/O | I/O |
| 39 | I/O | I/O | I/O | I/O |
| 40 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} |
| 41 | GND | GND | GND | GND |
| 42 | I/O | I/O | I/O | I/O |
| 43 | I/O | I/O | I/O | I/O |
| 44 | I/O | I/O | I/O | I/O |
| 45 | I/O | I/O | I/O | I/O |
| 46 | I/O | I/O | I/O | I/O |
| 47 | I/O | I/O | I/O | I/O |
| 48 | I/O | I/O | I/O | I/O |
| 49 | I/O | I/O | I/O | I/O |
| 50 | I/O | I/O | I/O | I/O |
| 51 | I/O | I/O | I/O | I/O |
| 52 | GND | GND | GND | GND |

| Pin No. | A500K050 Function | A500K130 Function | A500K180 Function | A500K270 Function |
|---------|-------------------|-------------------|-------------------|-------------------|
| 53 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} |
| 54 | I/O | I/O | I/O | I/O |
| 55 | I/O | I/O | I/O | I/O |
| 56 | I/O | I/O | I/O | I/O |
| 57 | I/O | I/O | I/O | I/O |
| 58 | I/O | I/O | I/O | I/O |
| 59 | I/O | I/O | I/O | I/O |
| 60 | I/O | I/O | I/O | I/O |
| 61 | I/O | I/O | I/O | I/O |
| 62 | I/O | I/O | I/O | I/O |
| 63 | I/O | I/O | I/O | I/O |
| 64 | I/O | I/O | I/O | I/O |
| 65 | GND | GND | GND | GND |
| 66 | I/O | I/O | I/O | I/O |
| 67 | I/O | I/O | I/O | I/O |
| 68 | I/O | I/O | I/O | I/O |
| 69 | I/O | I/O | I/O | I/O |
| 70 | I/O | I/O | I/O | I/O |
| 71 | V _{DDL} | V _{DDL} | V _{DDL} | V _{DDL} |
| 72 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} |
| 73 | I/O | I/O | I/O | I/O |
| 74 | I/O | I/O | I/O | I/O |
| 75 | I/O | I/O | I/O | I/O |
| 76 | I/O | I/O | I/O | I/O |
| 77 | I/O | I/O | I/O | I/O |
| 78 | I/O | I/O | I/O | I/O |
| 79 | I/O | I/O | I/O | I/O |
| 80 | I/O | I/O | I/O | I/O |
| 81 | GND | GND | GND | GND |
| 82 | I/O | I/O | I/O | I/O |
| 83 | I/O | I/O | I/O | I/O |
| 84 | I/O | I/O | I/O | I/O |
| 85 | I/O | I/O | I/O | I/O |
| 86 | I/O | I/O | I/O | I/O |
| 87 | I/O | I/O | I/O | I/O |
| 88 | V _{DDL} | V _{DDL} | V _{DDL} | V _{DDL} |
| 89 | V _{DDP} | V _{DDP} | GND | V _{DDP} |
| 90 | I/O | I/O | I/O | I/O |
| 91 | I/O | I/O | I/O | I/O |
| 92 | I/O | I/O | I/O | I/O |
| 93 | I/O | I/O | I/O | I/O |
| 94 | I/O | I/O | I/O | I/O |
| 95 | I/O | I/O | I/O | I/O |
| 96 | I/O | I/O | I/O | I/O |
| 97 | GND | GND | GND | GND |
| 98 | I/O | I/O | I/O | I/O |
| 99 | I/O | I/O | I/O | I/O |
| 100 | I/O | I/O | I/O | I/O |
| 101 | I/O/TCK | I/O/TCK | I/O/TCK | I/O/TCK |
| 102 | I/O/TDI | I/O/TDI | I/O/TDI | I/O/TDI |
| 103 | I/O/TMS | I/O/TMS | I/O/TMS | I/O/TMS |
| 104 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} |

208-Pin PQFP (Continued)

| Pin No. | A500K050 Function | A500K130 Function | A500K180 Function | A500K270 Function | Pin No. | A500K050 Function | A500K130 Function | A500K180 Function | A500K270 Function |
|---------|-------------------|-------------------|-------------------|-------------------|---------|-------------------|-------------------|-------------------|-------------------|
| 105 | GND | GND | GND | GND | 157 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} |
| 106 | V _{PP} | V _{PP} | V _{PP} | V _{PP} | 158 | I/O | I/O | I/O | I/O |
| 107 | V _{PN} | V _{PN} | V _{PN} | V _{PN} | 159 | I/O | I/O | I/O | I/O |
| 108 | I/O/TDO | I/O/TDO | I/O/TDO | I/O/TDO | 160 | I/O | I/O | I/O | I/O |
| 109 | I/O/TRSTB | I/OTRSTB | I/OTRSTB | I/OTRSTB | 161 | I/O | I/O | I/O | I/O |
| 110 | I/O/RCK | I/O/RCK | I/O/RCK | I/O/RCK | 162 | GND | GND | GND | GND |
| 111 | I/O | I/O | I/O | I/O | 163 | I/O | I/O | I/O | I/O |
| 112 | I/O | I/O | I/O | I/O | 164 | I/O | I/O | I/O | I/O |
| 113 | I/O | I/O | I/O | I/O | 165 | I/O | I/O | I/O | I/O |
| 114 | I/O | I/O | I/O | I/O | 166 | I/O | I/O | I/O | I/O |
| 115 | I/O | I/O | I/O | I/O | 167 | I/O | I/O | I/O | I/O |
| 116 | I/O | I/O | I/O | I/O | 168 | I/O | I/O | I/O | I/O |
| 117 | I/O | I/O | I/O | I/O | 169 | I/O | I/O | I/O | I/O |
| 118 | I/O | I/O | I/O | I/O | 170 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} |
| 119 | I/O | I/O | I/O | I/O | 171 | V _{DDL} | V _{DDL} | V _{DDL} | V _{DDL} |
| 120 | I/O | I/O | I/O | I/O | 172 | I/O | I/O | I/O | I/O |
| 121 | I/O | I/O | I/O | I/O | 173 | I/O | I/O | I/O | I/O |
| 122 | GND | GND | GND | GND | 174 | I/O | I/O | I/O | I/O |
| 123 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} | 175 | I/O | I/O | I/O | I/O |
| 124 | I/O | I/O | I/O | I/O | 176 | I/O | I/O | I/O | I/O |
| 125 | I/O | I/O | I/O | I/O | 177 | I/O | I/O | I/O | I/O |
| 126 | V _{DDL} | V _{DDL} | V _{DDL} | V _{DDL} | 178 | GND | GND | GND | GND |
| 127 | I/O | I/O | I/O | I/O | 179 | I/O | I/O | I/O | I/O |
| 128 | I/O | I/O | I/O | I/O | 180 | I/O | I/O | I/O | I/O |
| 129 | I/O | I/O | I/O | I/O | 181 | I/O | I/O | I/O | I/O |
| 130 | GND | GND | GND | GND | 182 | I/O | I/O | I/O | I/O |
| 131 | I/O | I/O | I/O | I/O | 183 | I/O | I/O | I/O | I/O |
| 132 | I/O | I/O | I/O | I/O | 184 | I/O | I/O | I/O | I/O |
| 133 | G2 | G2 | G2 | G2 | 185 | I/O | I/O | I/O | I/O |
| 134 | G3 | G3 | G3 | G3 | 186 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} |
| 135 | I/O | I/O | I/O | I/O | 187 | V _{DDL} | V _{DDL} | V _{DDL} | V _{DDL} |
| 136 | I/O | I/O | I/O | I/O | 188 | I/O | I/O | I/O | I/O |
| 137 | I/O | I/O | I/O | I/O | 189 | I/O | I/O | I/O | I/O |
| 138 | V _{DDP} | V _{DDL} | V _{DDP} | V _{DDP} | 190 | I/O | I/O | I/O | I/O |
| 139 | I/O | I/O | I/O | I/O | 191 | I/O | I/O | I/O | I/O |
| 140 | I/O | I/O | I/O | I/O | 192 | I/O | I/O | I/O | I/O |
| 141 | GND | GND | GND | GND | 193 | I/O | I/O | I/O | I/O |
| 142 | V _{DDL} | V _{DDL} | V _{DDL} | V _{DDL} | 194 | I/O | I/O | I/O | I/O |
| 143 | I/O | I/O | I/O | I/O | 195 | GND | GND | GND | GND |
| 144 | I/O | I/O | I/O | I/O | 196 | I/O | I/O | I/O | I/O |
| 145 | I/O | I/O | I/O | I/O | 197 | I/O | I/O | I/O | I/O |
| 146 | I/O | I/O | I/O | I/O | 198 | I/O | I/O | I/O | I/O |
| 147 | I/O | I/O | I/O | I/O | 199 | I/O | I/O | I/O | I/O |
| 148 | I/O | I/O | I/O | I/O | 200 | I/O | I/O | I/O | I/O |
| 149 | I/O | I/O | I/O | I/O | 201 | I/O | I/O | I/O | I/O |
| 150 | I/O | I/O | I/O | I/O | 202 | I/O | I/O | I/O | I/O |
| 151 | I/O | I/O | I/O | I/O | 203 | I/O | I/O | I/O | I/O |
| 152 | I/O | I/O | I/O | I/O | 204 | I/O | I/O | I/O | I/O |
| 153 | I/O | I/O | I/O | I/O | 205 | I/O | I/O | I/O | I/O |
| 154 | I/O | I/O | I/O | I/O | 206 | I/O | I/O | I/O | I/O |
| 155 | I/O | I/O | I/O | I/O | 207 | I/O | I/O | I/O | I/O |
| 156 | GND | GND | GND | GND | 208 | V _{DDP} | V _{DDP} | V _{DDP} | V _{DDP} |

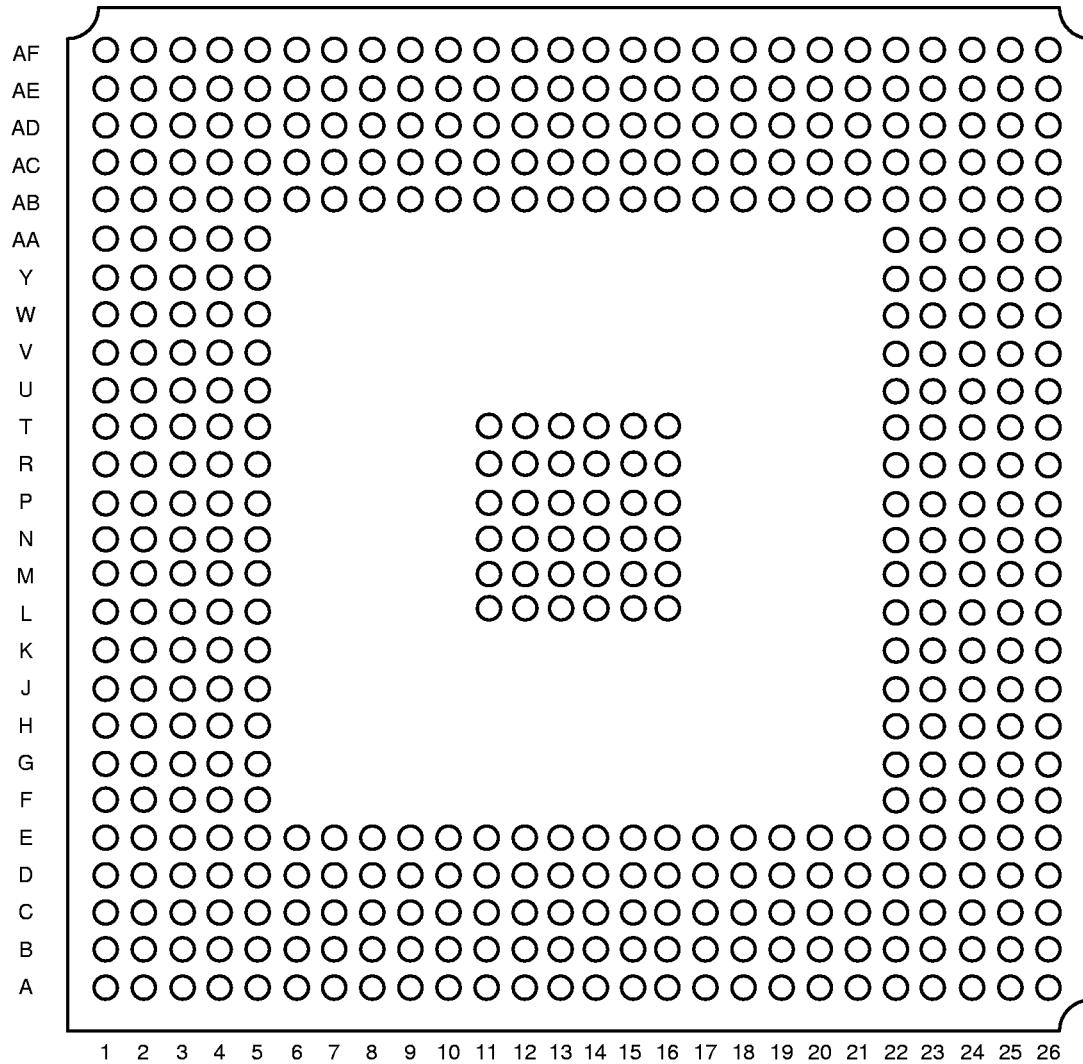
Package Pin Assignments (continued)**272-Pin PBGA**

272-Pin PBGA

| Ext. Ball | A500K050 Function | A500K130 Function | Ext. Ball | A500K050 Function | A500K130 Function | Ext. Ball | A500K050 Function | A500K130 Function |
|-----------|-------------------|-------------------|-----------|-------------------|-------------------|-----------|-------------------|-------------------|
| A1 | I/O | I/O | C7 | I/O | I/O | F17 | V _{DDP} | V _{DDP} |
| A2 | I/O | I/O | C8 | I/O | I/O | F18 | I/O | I/O |
| A3 | I/O | I/O | C9 | I/O | I/O | F19 | I/O | I/O |
| A4 | I/O | I/O | C10 | I/O | I/O | F20 | I/O | I/O |
| A5 | I/O | I/O | C11 | I/O | I/O | G1 | I/O | I/O |
| A6 | I/O | I/O | C12 | I/O | I/O | G2 | I/O | I/O |
| A7 | I/O | I/O | C13 | I/O | I/O | G3 | I/O | I/O |
| A8 | I/O | I/O | C14 | I/O | I/O | G4 | I/O | I/O |
| A9 | I/O | I/O | C15 | I/O | I/O | G17 | I/O | I/O |
| A10 | I/O | I/O | C16 | I/O | I/O | G18 | I/O | I/O |
| A11 | I/O | I/O | C17 | I/O | I/O | G19 | I/O | I/O |
| A12 | I/O | I/O | C18 | I/O | I/O | G20 | I/O | I/O |
| A13 | I/O | I/O | C19 | I/O | I/O | H1 | I/O | I/O |
| A14 | I/O | I/O | C20 | I/O | I/O | H2 | I/O | I/O |
| A15 | I/O | I/O | D1 | I/O | I/O | H3 | I/O | I/O |
| A16 | I/O | I/O | D2 | I/O | I/O | H4 | I/O | I/O |
| A17 | I/O | I/O | D3 | I/O | I/O | H17 | I/O | I/O |
| A18 | I/O | I/O | D4 | V _{DDP} | V _{DDP} | H18 | I/O | I/O |
| A19 | I/O | I/O | D5 | V _{DDP} | V _{DDP} | H19 | I/O | I/O |
| A20 | I/O | I/O | D6 | V _{DDP} | V _{DDP} | H20 | G3 | G3 |
| B1 | I/O | I/O | D7 | I/O | I/O | J1 | I/O | I/O |
| B2 | I/O | I/O | D8 | V _{DDL} | V _{DDL} | J2 | G0 | G0 |
| B3 | I/O | I/O | D9 | V _{DDL} | V _{DDL} | J3 | G1 | G1 |
| B4 | I/O | I/O | D10 | V _{DDL} | V _{DDL} | J4 | V _{DDL} | V _{DDL} |
| B5 | I/O | I/O | D11 | V _{DDL} | V _{DDL} | J9 | GND | GND |
| B6 | I/O | I/O | D12 | V _{DDL} | V _{DDL} | J10 | GND | GND |
| B7 | I/O | I/O | D13 | V _{DDL} | V _{DDL} | J11 | GND | GND |
| B8 | I/O | I/O | D14 | I/O | I/O | J12 | GND | GND |
| B9 | I/O | I/O | D15 | V _{DDP} | V _{DDP} | J17 | V _{DDL} | V _{DDL} |
| B10 | I/O | I/O | D16 | V _{DDP} | V _{DDP} | J18 | G2 | G2 |
| B11 | I/O | I/O | D17 | V _{DDP} | V _{DDP} | J19 | I/O | I/O |
| B12 | I/O | I/O | D18 | I/O | I/O | J20 | I/O | I/O |
| B13 | I/O | I/O | D19 | I/O | I/O | K1 | I/O | I/O |
| B14 | I/O | I/O | D20 | I/O | I/O | K2 | I/O | I/O |
| B15 | I/O | I/O | E1 | I/O | I/O | K3 | I/O | I/O |
| B16 | I/O | I/O | E2 | I/O | I/O | K4 | V _{DDL} | V _{DDL} |
| B17 | I/O | I/O | E3 | I/O | I/O | K9 | GND | GND |
| B18 | I/O | I/O | E4 | V _{DDP} | V _{DDP} | K10 | GND | GND |
| B19 | I/O | I/O | E17 | V _{DDP} | V _{DDP} | K11 | GND | GND |
| B20 | I/O | I/O | E18 | I/O | I/O | K12 | GND | GND |
| C1 | I/O | I/O | E19 | I/O | I/O | K17 | V _{DDL} | V _{DDL} |
| C2 | I/O | I/O | E20 | I/O | I/O | K18 | I/O | I/O |
| C3 | I/O | I/O | F1 | I/O | I/O | K19 | I/O | I/O |
| C4 | I/O | I/O | F2 | I/O | I/O | K20 | I/O | I/O |
| C5 | I/O | I/O | F3 | I/O | I/O | L1 | I/O | I/O |
| C6 | I/O | I/O | F4 | V _{DDP} | V _{DDP} | L2 | I/O | I/O |

272-Pin PBGA (Continued)

| Ext. Ball | A500K050 Function | A500K130 Function | Ext. Ball | A500K050 Function | A500K130 Function | Ext. Ball | A500K050 Function | A500K130 Function |
|-----------|-------------------|-------------------|-----------|-------------------|-------------------|-----------|-------------------|-------------------|
| L3 | I/O | I/O | T1 | I/O | I/O | V19 | I/O | I/O |
| L4 | V _{DDL} | V _{DDL} | T2 | I/O | I/O | V20 | I/O | I/O |
| L9 | GND | GND | T3 | I/O | I/O | W1 | I/O | I/O |
| L10 | GND | GND | T4 | V _{DDP} | V _{DDP} | W2 | I/O | I/O |
| L11 | GND | GND | T17 | V _{DDP} | V _{DDP} | W3 | I/O | I/O |
| L12 | GND | GND | T18 | I/O | I/O | W4 | I/O | I/O |
| L17 | V _{DDL} | V _{DDL} | T19 | I/O | I/O | W5 | I/O | I/O |
| L18 | I/O | I/O | T20 | I/O | I/O | W6 | I/O | I/O |
| L19 | I/O | I/O | U1 | I/O | I/O | W7 | I/O | I/O |
| L20 | I/O | I/O | U2 | I/O | I/O | W8 | I/O | I/O |
| M1 | I/O | I/O | U3 | I/O | I/O | W9 | I/O | I/O |
| M2 | I/O | I/O | U4 | V _{DDP} | V _{DDP} | W10 | I/O | I/O |
| M3 | I/O | I/O | U5 | V _{DDP} | V _{DDP} | W11 | I/O | I/O |
| M4 | V _{DDL} | V _{DDL} | U6 | V _{DDP} | V _{DDP} | W12 | I/O | I/O |
| M9 | GND | GND | U7 | I/O | I/O | W13 | I/O | I/O |
| M10 | GND | GND | U8 | V _{DDL} | V _{DDL} | W14 | I/O | I/O |
| M11 | GND | GND | U9 | V _{DDL} | V _{DDL} | W15 | I/O | I/O |
| M12 | GND | GND | U10 | V _{DDL} | V _{DDL} | W16 | I/O | I/O |
| M17 | V _{DDL} | V _{DDL} | U11 | V _{DDL} | V _{DDL} | W17 | I/O/TCK | I/O/TCK |
| M18 | I/O | I/O | U12 | V _{DDL} | V _{DDL} | W18 | V _{PP} | V _{PP} |
| M19 | I/O | I/O | U13 | V _{DDL} | V _{DDL} | W19 | I/O/TRSTB | I/O/TRSTB |
| M20 | I/O | I/O | U14 | I/O | I/O | W20 | I/O | I/O |
| N1 | I/O | I/O | U15 | V _{DDP} | V _{DDP} | Y1 | I/O | I/O |
| N2 | I/O | I/O | U16 | V _{DDP} | V _{DDP} | Y2 | I/O | I/O |
| N3 | I/O | I/O | U17 | V _{DDP} | V _{DDP} | Y3 | I/O | I/O |
| N4 | V _{DDL} | V _{DDL} | U18 | I/O/RCK | I/O/RCK | Y4 | I/O | I/O |
| N17 | V _{DDL} | V _{DDL} | U19 | I/O | I/O | Y5 | I/O | I/O |
| N18 | I/O | I/O | U20 | I/O | I/O | Y6 | I/O | I/O |
| N19 | I/O | I/O | V1 | I/O | I/O | Y7 | I/O | I/O |
| N20 | I/O | I/O | V2 | I/O | I/O | Y8 | I/O | I/O |
| P1 | I/O | I/O | V3 | I/O | I/O | Y9 | I/O | I/O |
| P2 | I/O | I/O | V4 | I/O | I/O | Y10 | I/O | I/O |
| P3 | I/O | I/O | V5 | I/O | I/O | Y11 | I/O | I/O |
| P4 | V _{DDP} | V _{DDP} | V6 | I/O | I/O | Y12 | I/O | I/O |
| P17 | V _{DDP} | V _{DDP} | V7 | I/O | I/O | Y13 | I/O | I/O |
| P18 | I/O | I/O | V8 | I/O | I/O | Y14 | I/O | I/O |
| P19 | I/O | I/O | V9 | I/O | I/O | Y15 | I/O | I/O |
| P20 | I/O | I/O | V10 | I/O | I/O | Y16 | I/O | I/O |
| R1 | I/O | I/O | V11 | I/O | I/O | Y17 | I/O | I/O |
| R2 | I/O | I/O | V12 | I/O | I/O | Y18 | I/O/TDI | I/O/TDI |
| R3 | I/O | I/O | V13 | I/O | I/O | Y19 | V _{PN} | V _{PN} |
| R4 | V _{DDP} | V _{DDP} | V14 | I/O | I/O | Y20 | I/O | I/O |
| R17 | V _{DDP} | V _{DDP} | V15 | I/O | I/O | | | |
| R18 | I/O | I/O | V16 | I/O | I/O | | | |
| R19 | I/O | I/O | V17 | I/O/TMS | I/O/TMS | | | |
| R20 | I/O | I/O | V18 | I/O/TDO | I/O/TDO | | | |

Package Pin Assignments (continued)**456-Pin PBGA**

456-Pin PBGA

| Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function | Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function |
|-----------|-------------------|-------------------|-------------------|-----------|-------------------|-------------------|-------------------|
| A1 | V _{DDP} | V _{DDP} | V _{DDP} | AB11 | IO | I/O | I/O |
| A2 | V _{DDP} | V _{DDP} | V _{DDP} | AB12 | IO | I/O | I/O |
| A3 | NC | I/O | I/O | AB13 | IO | I/O | I/O |
| A4 | IO | I/O | I/O | AB14 | IO | I/O | I/O |
| A5 | IO | I/O | I/O | AB15 | IO | I/O | I/O |
| A6 | NC | I/O | I/O | AB16 | IO | I/O | I/O |
| A7 | IO | I/O | I/O | AB17 | IO | I/O | I/O |
| A8 | NC | I/O | I/O | AB18 | IO | I/O | I/O |
| A9 | NC | I/O | I/O | AB19 | IO | I/O | I/O |
| A10 | IO | I/O | I/O | AB20 | V _{DDL} | V _{DDL} | V _{DDL} |
| A11 | NC | I/O | I/O | AB21 | V _{DDL} | V _{DDL} | V _{DDL} |
| A12 | NC | I/O | I/O | AB22 | V _{DDL} | V _{DDL} | V _{DDL} |
| A13 | IO | I/O | I/O | AB23 | IO | I/O | I/O |
| A14 | NC | I/O | I/O | AB24 | IO | I/O | I/O |
| A15 | NC | I/O | I/O | AB25 | IO | I/O | I/O |
| A16 | IO | I/O | I/O | AB26 | IO | I/O | I/O |
| A17 | NC | I/O | I/O | AC1 | IO | I/O | I/O |
| A18 | NC | I/O | I/O | AC2 | IO | I/O | I/O |
| A19 | IO | I/O | I/O | AC3 | IO | I/O | I/O |
| A20 | NC | I/O | I/O | AC4 | V _{DDP} | V _{DDP} | V _{DDP} |
| A21 | NC | I/O | I/O | AC5 | IO | I/O | I/O |
| A22 | IO | I/O | I/O | AC6 | IO | I/O | I/O |
| A23 | NC | I/O | I/O | AC7 | IO | I/O | I/O |
| A24 | NC | I/O | I/O | AC8 | IO | I/O | I/O |
| A25 | V _{DDP} | V _{DDP} | V _{DDP} | AC9 | IO | I/O | I/O |
| A26 | V _{DDP} | V _{DDP} | V _{DDP} | AC10 | IO | I/O | I/O |
| AA1 | IO | I/O | I/O | AC11 | IO | I/O | I/O |
| AA2 | IO | I/O | I/O | AC12 | IO | I/O | I/O |
| AA3 | IO | I/O | I/O | AC13 | IO | I/O | I/O |
| AA4 | IO | I/O | I/O | AC14 | IO | I/O | I/O |
| AA5 | V _{DDL} | V _{DDL} | V _{DDL} | AC15 | IO | I/O | I/O |
| AA22 | V _{DDL} | V _{DDL} | V _{DDL} | AC16 | IO | I/O | I/O |
| AA23 | IO | I/O | I/O | AC17 | IO | I/O | I/O |
| AA24 | IO | I/O | I/O | AC18 | IO | I/O | I/O |
| AA25 | IO | I/O | I/O | AC19 | IO | I/O | I/O |
| AA26 | NC | I/O | I/O | AC20 | IO | I/O | I/O |
| AB1 | NC | I/O | I/O | AC21 | IO/TMS | I/O/TMS | I/O/TMS |
| AB2 | IO | I/O | I/O | AC22 | IO/TDO | I/O/TDO | I/O/TDO |
| AB3 | IO | I/O | I/O | AC23 | V _{DDP} | V _{DDP} | V _{DDP} |
| AB4 | IO | I/O | I/O | AC24 | IO/RCK | I/O/RCK | I/O/RCK |
| AB5 | V _{DDL} | V _{DDL} | V _{DDL} | AC25 | IO | I/O | I/O |
| AB6 | V _{DDL} | V _{DDL} | V _{DDL} | AC26 | NC | I/O | I/O |
| AB7 | V _{DDL} | V _{DDL} | V _{DDL} | AD1 | NC | I/O | I/O |
| AB8 | IO | I/O | I/O | AD2 | IO | I/O | I/O |
| AB9 | IO | I/O | I/O | AD3 | V _{DDP} | V _{DDP} | V _{DDP} |
| AB10 | IO | I/O | I/O | AD4 | IO | I/O | I/O |

Note: NC = No Connection

456-Pin PBGA (Continued)

| Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function | Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function |
|-----------|-------------------|-------------------|-------------------|-----------|-------------------|-------------------|-------------------|
| AD5 | IO | I/O | I/O | AE25 | V _{DDP} | V _{DDP} | V _{DDP} |
| AD6 | IO | I/O | I/O | AE26 | V _{DDP} | V _{DDP} | V _{DDP} |
| AD7 | IO | I/O | I/O | AF1 | V _{DDP} | V _{DDP} | V _{DDP} |
| AD8 | IO | I/O | I/O | AF2 | V _{DDP} | V _{DDP} | V _{DDP} |
| AD9 | IO | I/O | I/O | AF3 | NC | I/O | I/O |
| AD10 | IO | I/O | I/O | AF4 | NC | I/O | I/O |
| AD11 | IO | I/O | I/O | AF5 | IO | I/O | I/O |
| AD12 | IO | I/O | I/O | AF6 | NC | I/O | I/O |
| AD13 | IO | I/O | I/O | AF7 | NC | I/O | I/O |
| AD14 | IO | I/O | I/O | AF8 | IO | I/O | I/O |
| AD15 | IO | I/O | I/O | AF9 | NC | I/O | I/O |
| AD16 | IO | I/O | I/O | AF10 | NC | I/O | I/O |
| AD17 | IO | I/O | I/O | AF11 | IO | I/O | I/O |
| AD18 | IO | I/O | I/O | AF12 | NC | I/O | I/O |
| AD19 | IO | I/O | I/O | AF13 | NC | I/O | I/O |
| AD20 | IO | I/O | I/O | AF14 | IO | I/O | I/O |
| AD21 | IO/TCK | I/O/TCK | I/O/TCK | AF15 | NC | I/O | I/O |
| AD22 | V _{PP} | V _{PP} | V _{PP} | AF16 | NC | I/O | I/O |
| AD23 | IO | I/O | I/O | AF17 | IO | I/O | I/O |
| AD24 | V _{DDP} | V _{DDP} | V _{DDP} | AF18 | NC | I/O | I/O |
| AD25 | IO | I/O | I/O | AF19 | NC | I/O | I/O |
| AD26 | NC | I/O | I/O | AF20 | IO | I/O | I/O |
| AE1 | V _{DDP} | V _{DDP} | V _{DDP} | AF21 | NC | I/O | I/O |
| AE2 | V _{DDP} | V _{DDP} | V _{DDP} | AF22 | IO | I/O | I/O |
| AE3 | IO | I/O | I/O | AF23 | IO/TDI | IO/TDI | IO/TDI |
| AE4 | IO | I/O | I/O | AF24 | NC | I/O | I/O |
| AE5 | IO | I/O | I/O | AF25 | V _{DDP} | V _{DDP} | V _{DDP} |
| AE6 | IO | I/O | I/O | AF26 | V _{DDP} | V _{DDP} | V _{DDP} |
| AE7 | IO | I/O | I/O | B1 | V _{DDP} | V _{DDP} | V _{DDP} |
| AE8 | IO | I/O | I/O | B2 | V _{DDP} | V _{DDP} | V _{DDP} |
| AE9 | IO | I/O | I/O | B3 | IO | I/O | I/O |
| AE10 | IO | I/O | I/O | B4 | IO | I/O | I/O |
| AE11 | IO | I/O | I/O | B5 | IO | I/O | I/O |
| AE12 | IO | I/O | I/O | B6 | IO | I/O | I/O |
| AE13 | IO | I/O | I/O | B7 | IO | I/O | I/O |
| AE14 | IO | I/O | I/O | B8 | IO | I/O | I/O |
| AE15 | IO | I/O | I/O | B9 | IO | I/O | I/O |
| AE16 | IO | I/O | I/O | B10 | IO | I/O | I/O |
| AE17 | IO | I/O | I/O | B11 | IO | I/O | I/O |
| AE18 | IO | I/O | I/O | B12 | IO | I/O | I/O |
| AE19 | IO | I/O | I/O | B13 | IO | I/O | I/O |
| AE20 | IO | I/O | I/O | B14 | IO | I/O | I/O |
| AE21 | IO | I/O | I/O | B15 | IO | I/O | I/O |
| AE22 | IO | I/O | I/O | B16 | IO | I/O | I/O |
| AE23 | V _{PN} | V _{PN} | V _{PN} | B17 | IO | I/O | I/O |
| AE24 | IO/TRSTB | I/O/TRSTB | I/O/TRSTB | B18 | IO | I/O | I/O |

Note: NC = No Connection

456-Pin PBGA (Continued)

| Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function | Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function |
|-----------|-------------------|-------------------|-------------------|-----------|-------------------|-------------------|-------------------|
| B19 | IO | I/O | I/O | D13 | IO | I/O | I/O |
| B20 | IO | I/O | I/O | D14 | IO | I/O | I/O |
| B21 | IO | I/O | I/O | D15 | IO | I/O | I/O |
| B22 | IO | I/O | I/O | D16 | IO | I/O | I/O |
| B23 | IO | I/O | I/O | D17 | IO | I/O | I/O |
| B24 | IO | I/O | I/O | D18 | IO | I/O | I/O |
| B25 | V _{DDP} | V _{DDP} | V _{DDP} | D19 | IO | I/O | I/O |
| B26 | V _{DDP} | V _{DDP} | V _{DDP} | D20 | IO | I/O | I/O |
| C1 | V _{DDP} | V _{DDP} | V _{DDP} | D21 | IO | I/O | I/O |
| C2 | IO | I/O | I/O | D22 | IO | I/O | I/O |
| C3 | V _{DDP} | V _{DDP} | V _{DDP} | D23 | V _{DDP} | V _{DDP} | V _{DDP} |
| C4 | IO | I/O | I/O | D24 | IO | I/O | I/O |
| C5 | IO | I/O | I/O | D25 | IO | I/O | I/O |
| C6 | IO | I/O | I/O | D26 | IO | I/O | I/O |
| C7 | IO | I/O | I/O | E1 | NC | I/O | I/O |
| C8 | IO | I/O | I/O | E2 | IO | I/O | I/O |
| C9 | IO | I/O | I/O | E3 | IO | I/O | I/O |
| C10 | IO | I/O | I/O | E4 | IO | I/O | I/O |
| C11 | IO | I/O | I/O | E5 | V _{DDL} | V _{DDL} | V _{DDL} |
| C12 | IO | I/O | I/O | E6 | V _{DDL} | V _{DDL} | V _{DDL} |
| C13 | IO | I/O | I/O | E7 | V _{DDL} | V _{DDL} | V _{DDL} |
| C14 | IO | I/O | I/O | E8 | V _{DDL} | V _{DDL} | V _{DDL} |
| C15 | IO | I/O | I/O | E9 | IO | I/O | I/O |
| C16 | IO | I/O | I/O | E10 | IO | I/O | I/O |
| C17 | IO | I/O | I/O | E11 | IO | I/O | I/O |
| C18 | IO | I/O | I/O | E12 | IO | I/O | I/O |
| C19 | IO | I/O | I/O | E13 | IO | I/O | I/O |
| C20 | IO | I/O | I/O | E14 | IO | I/O | I/O |
| C21 | IO | I/O | I/O | E15 | IO | I/O | I/O |
| C22 | IO | I/O | I/O | E16 | IO | I/O | I/O |
| C23 | IO | I/O | I/O | E17 | IO | I/O | I/O |
| C24 | V _{DDP} | V _{DDP} | V _{DDP} | E18 | IO | I/O | I/O |
| C25 | IO | I/O | I/O | E19 | IO | I/O | I/O |
| C26 | NC | I/O | I/O | E20 | V _{DDL} | V _{DDL} | V _{DDL} |
| D1 | NC | I/O | I/O | E21 | V _{DDL} | V _{DDL} | V _{DDL} |
| D2 | IO | I/O | I/O | E22 | V _{DDL} | V _{DDL} | V _{DDL} |
| D3 | IO | I/O | I/O | E23 | IO | I/O | I/O |
| D4 | V _{DDP} | V _{DDP} | V _{DDP} | E24 | IO | I/O | I/O |
| D5 | IO | I/O | I/O | E25 | IO | I/O | I/O |
| D6 | IO | I/O | I/O | E26 | IO | I/O | I/O |
| D7 | IO | I/O | I/O | F1 | IO | I/O | I/O |
| D8 | IO | I/O | I/O | F2 | IO | I/O | I/O |
| D9 | IO | I/O | I/O | F3 | IO | I/O | I/O |
| D10 | IO | I/O | I/O | F4 | IO | I/O | I/O |
| D11 | IO | I/O | I/O | F5 | V _{DDL} | V _{DDL} | V _{DDL} |
| D12 | IO | I/O | I/O | F22 | V _{DDL} | V _{DDL} | V _{DDL} |

Note: NC = No Connection

456-Pin PBGA (Continued)

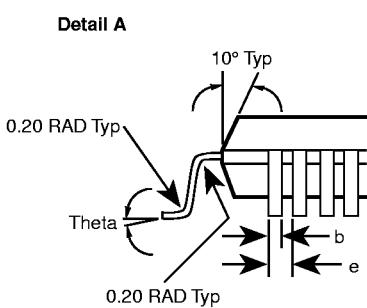
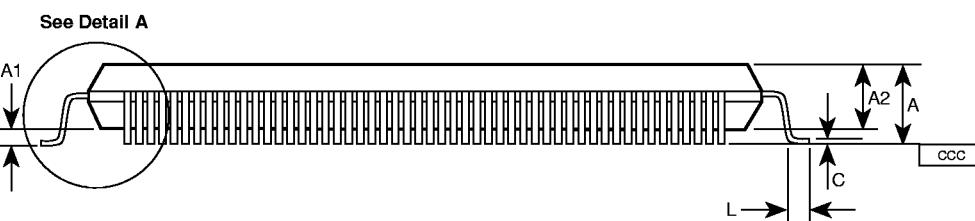
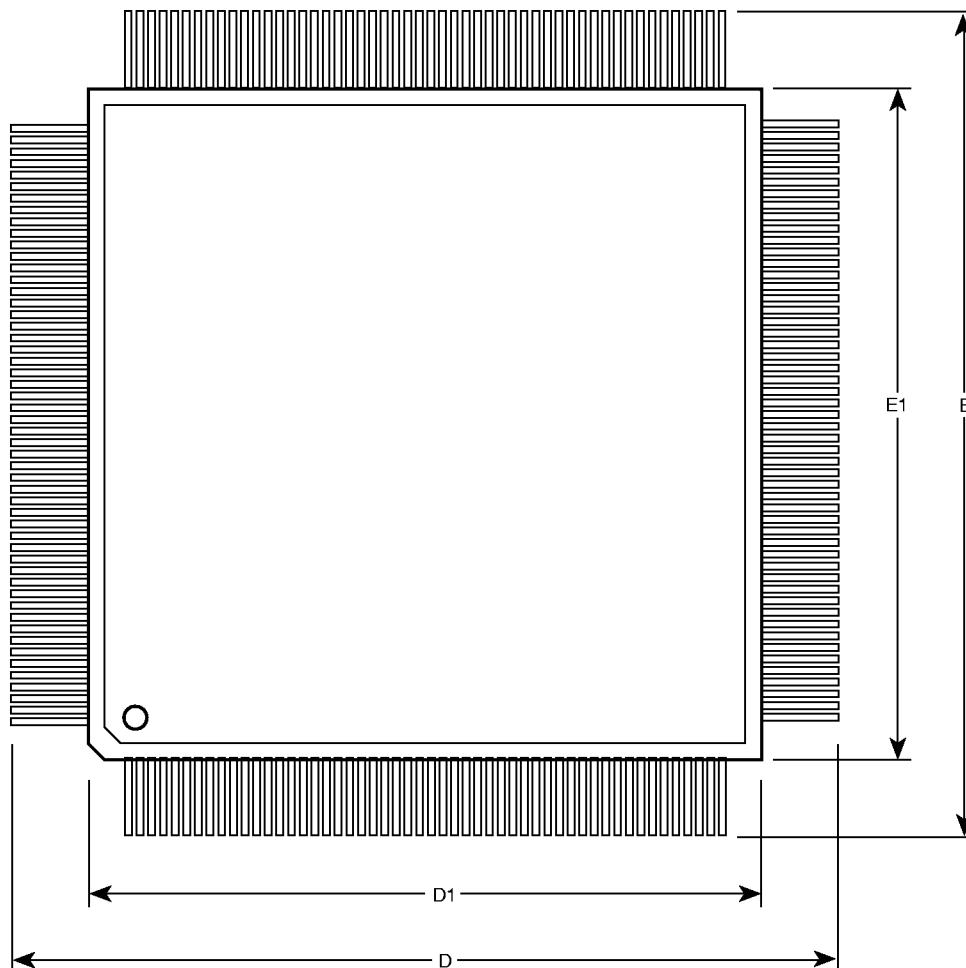
| Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function | Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function |
|-----------|-------------------|-------------------|-------------------|-----------|-------------------|-------------------|-------------------|
| F23 | IO | I/O | I/O | L3 | IO | I/O | I/O |
| F24 | IO | I/O | I/O | L4 | IO | I/O | I/O |
| F25 | IO | I/O | I/O | L5 | IO | I/O | I/O |
| F26 | NC | I/O | I/O | L11 | GND | GND | GND |
| G1 | NC | I/O | I/O | L12 | GND | GND | GND |
| G2 | IO | I/O | I/O | L13 | GND | GND | GND |
| G3 | IO | I/O | I/O | L14 | GND | GND | GND |
| G4 | IO | I/O | I/O | L15 | GND | GND | GND |
| G5 | V _{DDL} | V _{DDL} | V _{DDL} | L16 | GND | GND | GND |
| G22 | V _{DDL} | V _{DDL} | V _{DDL} | L22 | IO | I/O | I/O |
| G23 | IO | I/O | I/O | L23 | IO | I/O | I/O |
| G24 | IO | I/O | I/O | L24 | IO | I/O | I/O |
| G25 | IO | I/O | I/O | L25 | IO | I/O | I/O |
| G26 | IO | I/O | I/O | L26 | NC | I/O | I/O |
| H1 | NC | I/O | I/O | M1 | G2 | G1 | G1 |
| H2 | IO | I/O | I/O | M2 | G1 | G0 | G0 |
| H3 | IO | I/O | I/O | M3 | IO | I/O | I/O |
| H4 | IO | I/O | I/O | M4 | IO | I/O | I/O |
| H5 | V _{DDL} | V _{DDL} | V _{DDL} | M5 | IO | I/O | I/O |
| H22 | V _{DDL} | V _{DDL} | V _{DDL} | M11 | GND | GND | GND |
| H23 | IO | I/O | I/O | M12 | GND | GND | GND |
| H24 | IO | I/O | I/O | M13 | GND | GND | GND |
| H25 | IO | I/O | I/O | M14 | GND | GND | GND |
| H26 | NC | I/O | I/O | M15 | GND | GND | GND |
| J1 | IO | I/O | I/O | M16 | GND | GND | GND |
| J2 | IO | I/O | I/O | M22 | G4 | G3 | G3 |
| J3 | IO | I/O | I/O | M23 | IO | I/O | I/O |
| J4 | IO | I/O | I/O | M24 | IO | I/O | I/O |
| J5 | IO | I/O | I/O | M25 | IO | I/O | I/O |
| J22 | IO | I/O | I/O | M26 | NC | I/O | I/O |
| J23 | IO | I/O | I/O | N1 | NC | I/O | I/O |
| J24 | IO | I/O | I/O | N2 | IO | I/O | I/O |
| J25 | IO | I/O | I/O | N3 | IO | I/O | I/O |
| J26 | NC | I/O | I/O | N4 | IO | I/O | I/O |
| K1 | NC | I/O | I/O | N5 | IO | I/O | I/O |
| K2 | IO | I/O | I/O | N11 | GND | GND | GND |
| K3 | IO | I/O | I/O | N12 | GND | GND | GND |
| K4 | IO | I/O | I/O | N13 | GND | GND | GND |
| K5 | IO | I/O | I/O | N14 | GND | GND | GND |
| K22 | IO | I/O | I/O | N15 | GND | GND | GND |
| K23 | IO | I/O | I/O | N16 | GND | GND | GND |
| K24 | IO | I/O | I/O | N22 | IO | I/O | I/O |
| K25 | IO | I/O | I/O | N23 | G3 | G2 | G2 |
| K26 | IO | I/O | I/O | N24 | IO | I/O | I/O |
| L1 | NC | I/O | I/O | N25 | IO | I/O | I/O |
| L2 | IO | I/O | I/O | N26 | IO | I/O | I/O |

Note: NC = No Connection

456-Pin PBGA (Continued)

| Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function | Ext. Ball | A500K130 Function | A500K180 Function | A500K270 Function |
|-----------|-------------------|-------------------|-------------------|-----------|-------------------|-------------------|-------------------|
| P1 | NC | I/O | I/O | T23 | IO | I/O | I/O |
| P2 | IO | I/O | I/O | T24 | IO | I/O | I/O |
| P3 | IO | I/O | I/O | T25 | IO | I/O | I/O |
| P4 | IO | I/O | I/O | T26 | IO | I/O | I/O |
| P5 | IO | I/O | I/O | U1 | NC | I/O | I/O |
| P11 | GND | GND | GND | U2 | IO | I/O | I/O |
| P12 | GND | GND | GND | U3 | IO | I/O | I/O |
| P13 | GND | GND | GND | U4 | IO | I/O | I/O |
| P14 | GND | GND | GND | U5 | IO | I/O | I/O |
| P15 | GND | GND | GND | U22 | IO | I/O | I/O |
| P16 | GND | GND | GND | U23 | IO | I/O | I/O |
| P22 | IO | I/O | I/O | U24 | IO | I/O | I/O |
| P23 | IO | I/O | I/O | U25 | IO | I/O | I/O |
| P24 | IO | I/O | I/O | U26 | NC | I/O | I/O |
| P25 | IO | I/O | I/O | V1 | IO | I/O | I/O |
| P26 | NC | I/O | I/O | V2 | IO | I/O | I/O |
| R1 | IO | I/O | I/O | V3 | IO | I/O | I/O |
| R2 | IO | I/O | I/O | V4 | IO | I/O | I/O |
| R3 | IO | I/O | I/O | V5 | IO | I/O | I/O |
| R4 | IO | I/O | I/O | V22 | IO | I/O | I/O |
| R5 | IO | I/O | I/O | V23 | IO | I/O | I/O |
| R11 | GND | GND | GND | V24 | IO | I/O | I/O |
| R12 | GND | GND | GND | V25 | IO | I/O | I/O |
| R13 | GND | GND | GND | V26 | NC | I/O | I/O |
| R14 | GND | GND | GND | W1 | NC | I/O | I/O |
| R15 | GND | GND | GND | W2 | IO | I/O | I/O |
| R16 | GND | GND | GND | W3 | IO | I/O | I/O |
| R22 | IO | I/O | I/O | W4 | IO | I/O | I/O |
| R23 | IO | I/O | I/O | W5 | V_{DDL} | V_{DDL} | V_{DDL} |
| R24 | IO | I/O | I/O | W22 | V_{DDL} | V_{DDL} | V_{DDL} |
| R25 | IO | I/O | I/O | W23 | IO | I/O | I/O |
| R26 | NC | I/O | I/O | W24 | IO | I/O | I/O |
| T1 | NC | I/O | I/O | W25 | IO | I/O | I/O |
| T2 | IO | I/O | I/O | W26 | IO | I/O | I/O |
| T3 | IO | I/O | I/O | Y1 | NC | I/O | I/O |
| T4 | IO | I/O | I/O | Y2 | IO | I/O | I/O |
| T5 | IO | I/O | I/O | Y3 | IO | I/O | I/O |
| T11 | GND | GND | GND | Y4 | IO | I/O | I/O |
| T12 | GND | GND | GND | Y5 | V_{DDL} | V_{DDL} | V_{DDL} |
| T13 | GND | GND | GND | Y22 | V_{DDL} | V_{DDL} | V_{DDL} |
| T14 | GND | GND | GND | Y23 | IO | I/O | I/O |
| T15 | GND | GND | GND | Y24 | IO | I/O | I/O |
| T16 | GND | GND | GND | Y25 | IO | I/O | I/O |
| T22 | IO | I/O | I/O | Y26 | NC | I/O | I/O |

Note: NC = No Connection

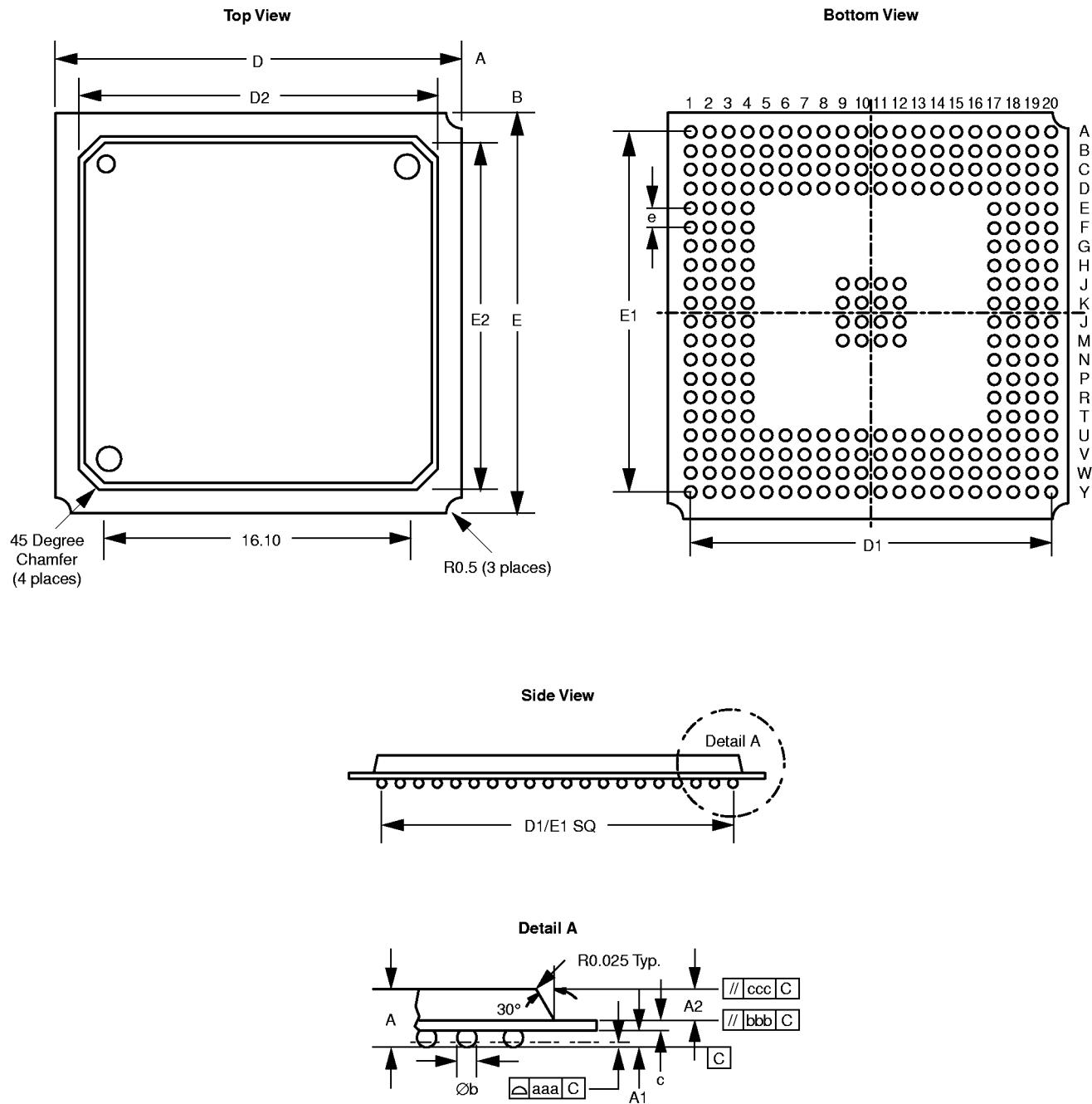
Package Mechanical Drawings**208-Pin PQFP**

Plastic Quad Flat Packages (PQFP)

| Jedec Equiv | PQFP 208 MO-143 | | |
|-------------|--------------------|-------|-------|
| Dimension | Min. | Nom. | Max. |
| A | | 3.70 | 4.10 |
| A1 | 0.25 | 0.38 | |
| A2 | 3.20 | 3.40 | 3.60 |
| b | 0.17 | | 0.27 |
| c | 0.09 | | 0.20 |
| ccc | | | 0.10 |
| D/E | 30.25 | 30.60 | 30.85 |
| D1/E1 | 27.90 | 28.00 | 28.10 |
| e | 0.50 BSC | | |
| L | 0.50 | 0.60 | 0.75 |
| Theta | 0 | | 7 deg |
| Diameter | 19.82 | 20.32 | 20.82 |

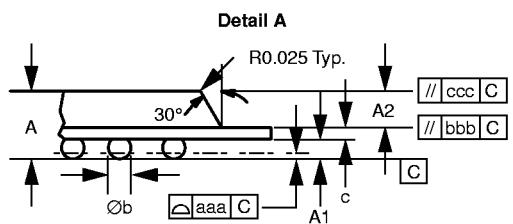
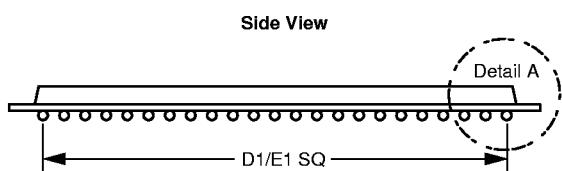
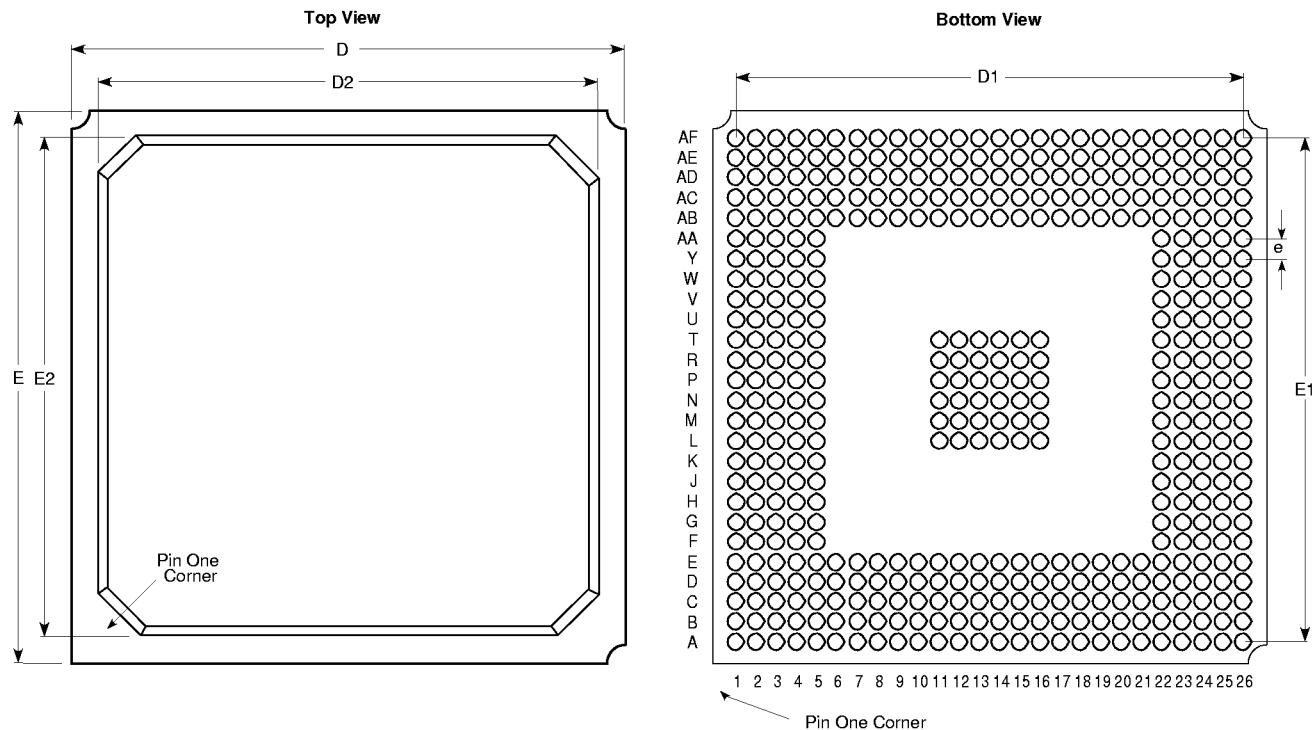
Notes:

1. All dimensions are in millimeters.
2. BSC - Basic Spacing between Centers.

Package Mechanical Drawings (Continued)**272-Pin PBGA**

Package Mechanical Drawings (Continued)

456-Pin PBGA



Plastic Ball Grid Array (PBGA)

| JEDEC Equivalent | PBGA272 | | | PBGA456 | | |
|------------------|-----------|-------|-------|------------|-------|-------|
| Dimension | Min. | Nom. | Max. | Min. | Nom. | Max. |
| A | 2.18 | 2.33 | 2.50 | 2.20 | 2.33 | 2.50 |
| A1 | 0.50 | 0.60 | 0.70 | 0.50 | 0.60 | 0.70 |
| A2 | 1.15 | 1.17 | 1.19 | 1.12 | 1.17 | 1.19 |
| aaa | | | 0.15 | | | 0.15 |
| bbb | | | 0.20 | | | 0.20 |
| b | 0.60 | 0.75 | 0.90 | 0.60 | 0.75 | 0.90 |
| c | 0.53 | 0.56 | 0.61 | 0.51 | 0.56 | 0.61 |
| ccc | | | 0.25 | | | 0.25 |
| D | 26.80 | 27.00 | 27.20 | 34.80 | 35.00 | 35.20 |
| D1 | 24.13 BSC | | | 31.75 BSC | | |
| D2 | 23.90 | 24.00 | 24.10 | 29.80 | 30.00 | 30.20 |
| E | 26.80 | 27.00 | 27.20 | 34.80 | 35.00 | 35.20 |
| E1 | 24.13 BSC | | | 31.075 BSC | | |
| E2 | 23.90 | 24.00 | 24.10 | 29.80 | 30.00 | 30.20 |
| e | 1.27 typ. | | | 1.27 typ. | | |
| Theta | 30° typ. | | | 30° typ. | | |

Notes:

1. All dimensions are in millimeters
2. BSC – Basic Spacing between Centers